MAX25220/MAX25221/ MAX25221B/MAX25221C

Automotive 4-Channel TFT-LCD Power Supplies with VCOM Buffer

General Description

The MAX25220/MAX25221/MAX25221B/MAX25221C 4-channel TFT-LCD power ICs provide symmetrical positive AVDD and negative NAVDD supplies as well as VG_{ON} and VG_{OFF} gate supplies. In addition, a VCOM buffer with output voltage range above and below ground and a temperature measurement block are integrated (MAX25221/B/C).

The devices contain nonvolatile memory so that the values of all outputs can be calibrated for the lifetime of the device (maximum five times).

Programming is carried out using the built-in I^2C interface, which can also be used to read back diagnostic information. A standalone mode is also available.

The temperature sensor interface block measures the temperature optionally, allowing the VCOM output voltage to be adjusted depending on the measured temperature.

The MAX25220/MAX25221/MAX25221B/MAX25221C are available in a TQFN package and operate in the -40°C to +125°C temperature range.

Applications

- Infotainment Displays
- Central Information Displays
- Instrument Clusters

Benefits and Features

- High Integration
  - Synchronous Boost Provides AVDD of 4.2V to 10.5V at up to 200mA
  - NAVDD Inverter Output at up to -200mA
  - 15mA VG_{ON} Output (7.6V to 20.2V) from 3x Regulated Charge Pump
  - VG_{OFF} (-18.2V to -5.6V) from Regulated Charge Pump at up to -15mA (Charge-Pump Doubler)
  - Controlled Sequencing during Power-On and Power-Off of All Rails
  - VCOM Output Range +1V to -2.49V in 6.83mV Steps (MAX25221/B/C)
  - NTC Input for Temperature Measurement/ Compensation (MAX25221/B/C)
- Low EMI
  - 420kHz/2.1MHz Switching Frequency with Spread Spectrum
- I^2C Control/Diagnostic Interface with FLTB (Interrupt) Output
  - UV Diagnostics on All Outputs
- Versatile
  - Nonvolatile Output Voltage Settings on AVDD/ NAVDD, VG_{ON}, VG_{OFF}, VCOM, and Sequencing
  - Supports Standalone Operation Mode after Programming
  - Compact 5mm x 5mm, 32-Pin TQFN Package
- AEC-Q100 Grade 1

Ordering Information appears at end of data sheet.

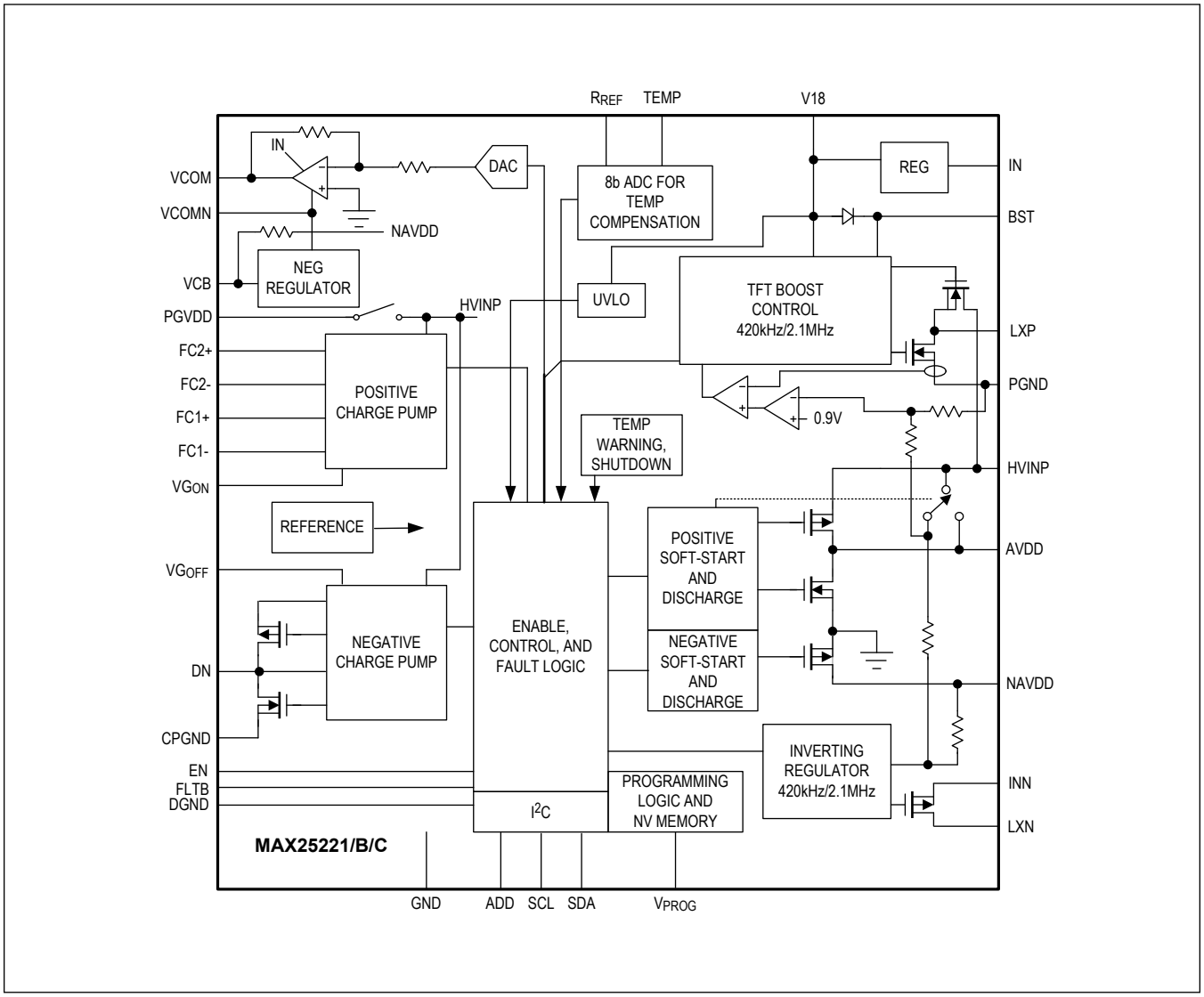
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Simplified Block Diagram



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Absolute Maximum Ratings

IN, INN to GND ..... -0.3V to +6V
IN to INN ..... -0.3V to +0.3V
V18 to GND ..... -0.3V to +2.2V
HVINP to GND ..... -0.3V to 16V
LXP, AVDD to GND ..... -0.3V to HVINP + 0.3V
BST to GND ..... -0.3V to +16V
BST to LXP ..... -0.3V to +2.2V
LXN to INN ..... -22V to +0.3V
PGND, CPGND, DGND to GND ..... -0.3V to +0.3V
VCB to GND ..... V18 - 22V to V18 + 0.3V
NAVDD to GND ..... V_{V18} - 16V to V_{V18} + 0.3V
VG_{OFF} to GND ..... V_{V18} - 22V to V_{V18} + 0.3V
VCOM to GND ..... VCOMN - 0.3V to IN + 0.3V
VCOMN to GND ..... V18 - 6V to V18 + 0.3V
PGVDD, FC1-, FC2-, DN to GND ..... -0.3V to HVINP + 0.3V
FC1+ to GND ..... -0.3V to PGVDD + 0.3V
FC2+ TO FC1+ ..... -0.3V to +22V
VG_{ON} to FC2+ ..... -0.3V to +22V
FC2+, VG_{ON} to GND ..... -0.3V to +24V
EN, FLTB, SCL, SDA to GND ..... -0.3V to +6V
ADD, TEMP, R_{REF} to GND ..... -0.3V to V18 + 0.3V
V_{PROG} to GND ..... -0.3V to +14V
Continuous Power Dissipation (Multilayer Board) (T_A = +70ºC, derate 21.3mW/ºC above +70ºC) 2222mW
Operating Temperature Range ..... -40°C to +125°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

32 TQFN

Package Code	T3255+6C
Outline Number	21-0140
Land Pattern Number	90-0603
Thermal Resistance, Single-Layer Board:	
Junction to Ambient (θ_{JA})	47°C/W
Junction to Case (θ_{JC})	3°C/W
Thermal Resistance, Four-Layer Board:	
Junction to Ambient (θ_{JA})	36°C/W
Junction to Case (θ_{JC})	3°C/W

32 TQFN-SW

Package Code	T3255Y+6C
Outline Number	21-100041
Land Pattern Number	90-100066
Thermal Resistance, Single-Layer Board:	
Junction to Ambient (θ_{JA})	47°C/W
Junction to Case (θ_{JC})	3°C/W
Thermal Resistance, Four-Layer Board:	
Junction to Ambient (θ_{JA})	36°C/W
Junction to Case (θ_{JC})	3°C/W

For the latest package outline information and land patterns (footprints), go to ***www.maximintegrated.com/packages***. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to ***www.maximintegrated.com/thermal-tutorial***.

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Electrical Characteristics

(V_{IN} = 3.3V, V_{INN} = 3.3V, Limits are 100% guaranteed between T_A = -40°C and T_A = +125°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
INPUT SUPPLY						
IN Voltage Range			2.65		5.5	V
IN UVLO Threshold	IN_UVLO_R	Rising	2.4	2.5	2.57	V
IN UVLO Hysteresis	IN_UVLO_HYS			100		mV
IN Shutdown Current	I_{IN_SHDN}	EN = GND, V_{IN} = 3.3V, T_A = +25°C		7	12	µA
IN Quiescent Current	I_{IN_Q}	V_{EN} = V_{IN} = 3.3V, no switching		1.5	2.5	mA
V18 REGULATOR						
V18 Output Voltage			1.72	1.8	1.88	V
V18 Current Limit			60			mA
V18 Undervoltage Lockout		V18 rising	1.6	1.65	1.7	V
V18 Undervoltage Hysteresis				150		mV
OSCILLATOR						
Operating Frequency	f_{BOOSTH}	f_{SW} bit = 0, dither disabled; switching frequency for boost, inverter, and charge pumps	1950	2100	2250	kHz
	f_{BOOSTL}	f_{SW} bit = 1, dither disabled; switching frequency for boost, inverter, and charge pumps	385	420	455	
Frequency Dither	f_{BOOSTD}			±6		%
BOOST REGULATOR						
HVINP Output Voltage Range	V_{HVINP}		V_{IN} + 1		10.5	V
AVDD Output Voltage Range			4.2		10.5	V
AVDD Adjustment Step Size				0.1		V
AVDD Output Regulation	V_{AVDD}	avdd[5:0] = 0x1A, full load current and input voltage range	6.664	6.8	6.936	V
Oscillator Maximum Duty Cycle		420kHz switching frequency	87	88.5	90	%
		2.1MHz switching frequency	84	87	90	
Low-Side Switch On-Resistance	LXP_RON_LS	I_{LXP} = 0.1A		0.1	0.2	Ω
Synchronous Rectifier On-Resistance				0.1	0.2	Ω
Synchronous Rectifier Zero-Crossing Threshold	ZX_TH			70		mA
LXP Leakage Current	LXP_L_LEAK	V_{EN} = 0V, V_{LXP} = 10.5V			20	µA
LXP Current Limit	I_{LIMPH}	Duty cycle = 50%	1.7	2	2.3	A
Soft-Start Period	t_{BOOST_SS}	Current-limit ramp		5		ms

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Electrical Characteristics (continued)

(V_{IN} = 3.3V, V_{INN} = 3.3V, Limits are 100% guaranteed between T_A = -40°C and T_A = +125°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
INVERTING REGULATOR						
Oscillator Maximum Duty Cycle		2.1MHz switching frequency	92	95		%
	INV_MAXDC	420kHz switching frequency	88	90		
V_{AVDD} + V_{NAVDD} Regulation Voltage	$V_{NAVDD_AVDD_REG}$	V_{INN} = 2.65V to 5.5V, V_{AVDD} = 6.8V, 1mA < I_{NAVDD} < 200mA, I_{AVDD} = same load as NAVDD	-34	0	+34	mV
LXN On-Resistance	LXN_RON	INN to LXN, I_{LXN} = 0.1A		0.25	0.5	Ω
LXN Leakage Current	LXN_LEAK	V_{IN} = 3.6V, V_{LXN} = V_{NAVDD} = -6.8V, T_A = +25°C			20	µA
LXN Current Limit	I_{LIMNH}	Duty cycle = 80%	1.55	1.9	2.25	A
Soft-Start Period	t_{INV_SS}	Current-limit ramp		5		ms
NAVDD Discharge Resistance				2		kΩ
POSITIVE CHARGE-PUMP REGULATOR						
VG_{ON} Threshold for Charge-Pump Switching Enable				V_{HVINP} - 0.8		V
FC1-, FC2- Switches Current Limit, High-Side			90	120		mA
FC1-, FC2- Switches Current Limit, Low-Side			72	100		mA
FC1-, FC2- to CPGND On-Resistance				4	6.5	Ω
FC1-, FC2- to HVINP On-Resistance				6	10.5	Ω
FC2+ to PGVDD, FC1+ to FC2+ and VG_{ON} to FC1+ Switches On-Resistance				2.5	4.5	Ω
VG_{ON} Voltage Range, I^2C Mode			7.6		20.2	V
VG_{ON} Adjustment Step Size, I^2C Mode				0.2		V
VG_{ON} Output Voltage	V_{VGON}	vgon[5:0] = 0x16, full load current and V_{HVINP} > 5V, charge-pump tripler	11.7	12	12.3	V
VG_{ON} Discharge Resistance			2.2	3	3.8	kΩ
NEGATIVE CHARGE-PUMP REGULATOR						
DN Current Limit			75	100		mA
VG_{OFF} Voltage Range, I^2C Mode			-18.2		-5.6	V
VG_{OFF} Adjustment Step Size, I^2C Mode				0.2		V
VG_{OFF} Output-Voltage Accuracy		vgoff[5:0] = 0x16, full load current and input voltage range, 420kHz operation.	-10.3	-10	-9.7	V

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Electrical Characteristics (continued)

(V_{IN} = 3.3V, V_{INN} = 3.3V, Limits are 100% guaranteed between T_A = -40°C and T_A = +125°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DN On-Resistance, High-Side				6	10	Ω
DN On-Resistance, Low-Side		I_{DN} = -10mA		3.5	6.5	Ω
VG_{OFF} Discharge Current				1.5		mA
SEQUENCE SWITCHES						
AVDD On-Resistance	R_{ONAVDD}	Between HVINP and AVDD, I_{AVDD} = 200mA		0.5	1	Ω
AVDD Current Limit	$ILIM_{POS}$		300		600	mA
AVDD Discharge Resistance				1.2		kΩ
PGVDD On-Resistance		(HVINP-PGVDD), I_{PGVDD} = 3mA		6	9	Ω
PGVDD Current Limit		Expires when PGVDD charging is completed	80	100		mA
FAULT PROTECTION						
Fault Timeout		tfault[1:0] = 10		60		ms
Fault Retry Time		tretry[1:0] = 10 or 11		1.9		s
FLTB Output Frequency		Standalone mode only	0.88	1	1.12	kHz
FLTB Output Duty Cycle, VG_{ON} or VG_{OFF} Fault		Standalone mode only		75		%
FLTB Output Duty Cycle with AVDD, NAVDD, or HVINP Fault		Standalone mode only		50		%
FLTB Output Duty Cycle, VCOM Fault		Standalone mode only		25		%
AVDD Undervoltage Fault Threshold		Relative measurement between HVINP and AVDD	80	85	90	%
AVDD Short-Circuit Fault Threshold		Relative measurement between HVINP and AVDD	35	40	45	%
NAVDD Undervoltage Fault Threshold		Measured with respect to AVDD	80	85	90	%
NAVDD Short-Circuit Fault Threshold		Measured with respect to AVDD	35	40	45	%
VG_{ON} Undervoltage Fault Threshold		Of set value	80	85	90	%
VG_{ON} Short-Circuit Fault Threshold		VG_{ON} falling, MAX25220ATJ/ MAX25221ATJ/MAX25221BATJ only		V_{HVINP} - 1.1		V
VG_{OFF} Undervoltage Fault Threshold		Of set value	80	85	90	%
VG_{OFF} Short-Circuit Fault Threshold		MAX25220ATJ/MAX25221ATJ/ MAX25221BATJ only	35	40	45	%
Short-Circuit and Overload Fault Delay				10		µs

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Electrical Characteristics (continued)

(V_{IN} = 3.3V, V_{INN} = 3.3V, Limits are 100% guaranteed between T_A = -40°C and T_A = +125°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
VCOM BUFFER						
VCOMN Output Voltage		I_{VCOM} = 120mA, V_{NAVDD} = -10.5V		-3.5	-3.2	V
VCB Output Current			5	12	21	mA
VCOM Output Current Limit, Sinking		Dynamic output current, t < t_{FAULT}	120	200	300	mA
VCOM Output Current Limit, Sourcing	$I_{LIMCOMP}$	Dynamic output current, t < t_{FAULT}	120	200	300	mA
VCOM Overcurrent Detection Threshold			60	70	85	% of $I_{LIMCOMP}$
VCOM Offset Voltage, Complete Range		V_{VCOM} = -2.49V and V_{VCOM} = +1V, no load	-25		+25	mV
VCOM Offset Voltage, +25°C		T_A = +25°C, VCOM = -0.5V	-6		+6	mV
VCOM Offset Voltage		VCOM = -0.5V	-10		+10	mV
VCOM Output Voltage Range		Temperature compensation disabled	-2.49		+1	V
VCOM DAC Step Size				6.83		mV
VCOM Buffer Slew Rate		C_{VCOM} = 10nF, VCOM from -2.49V to +1V		0.72		V/µs
VCOM Fault Threshold		Deviation from set voltage		±0.25		V
VCOM Fault Detection Filter Time		tfault[1:0] = 10		60		ms
VCOM Discharge Resistance		To GND	9	14	22	kΩ
R_{REF} INPUT						
R_{REF} Input Voltage Range			0		1.25	V
R_{REF} ADC Resolution				4.88		mV
R_{REF} Conversion Rate				128		kHz
TEMP Voltage	V_{TEMP}	I_{TEMP} = 10µA to 500µA		625		mV
TEMP Current Mirror Gain		I_{TEMP} = 10µA to 500µA		1		µA/µA
Internal Temperature Sensor Voltage		T_A = +25°C		620		mV
R_{REF} DAC Offset				5		mV
R_{REF} DAC Full-Scale Error				5		mV
R_{REF} DAC Gain Error			-0.4		+0.4	%
R_{REF} DAC Differential Non-linearity				0.5		LSB
R_{REF} DAC Integral Non-Linearity				0.5		LSB
LOGIC INPUTS AND OUTPUTS (EN, SCL, ADD, SDA)						
EN Glitch Filter	EN_BLK			10		µs

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Electrical Characteristics (continued)

(V_{IN} = 3.3V, V_{INN} = 3.3V, Limits are 100% guaranteed between T_A = -40°C and T_A = +125°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
EN Minimum Low Time for Reset		C_{V18} = 1µF	1			ms
EN Input Logic-High			1.22			V
EN Input Logic-Low					0.6	V
ADD Input Logic-High			1.22			V
ADD Input Logic-Low					0.66	V
ADD Input Pull-down Current				10	12	µA
SCL, SDA Input, Logic-High			1.22			V
SCL, SDA Input, Logic-Low					0.6	V
SCL Input Leakage Current			-1		+1	µA
FLTB, SDA Output Low Voltage	V_{OL}	Sinking 5mA			0.4	V
FLTB, SDA Output Leakage Current	I_{LEAK}	5.5V	-1		+1	µA
PROGRAMMING VOLTAGE						
V_{PROG} Voltage			8.2	8.5	8.8	V
V_{PROG} Voltage Undervoltage Threshold		V_{PROG} rising		8	8.2	V
V_{PROG} Voltage Overvoltage Threshold		V_{PROG} falling	8.8	9		V
V_{PROG} Input Current		During NV programming, T_A = +25°C		9	25	mA
NV Programming Time				16	20	ms
THERMAL SHUTDOWN						
Thermal Warning Threshold				125		°C
Thermal-Shutdown Threshold	T_{SHDN}			160		°C
Thermal-Shutdown Hysteresis	T_{SHDN_HYS}			15		°C
I²C INTERFACE						
Clock Frequency	f_{SCL}				0.4	MHz
Hold Time (Repeated) START	$t_{HD:STA}$		600			ns
SCL Low Time	t_{LOW}		1300			ns
SCL High Time	t_{HIGH}		600			ns
Setup Time (Repeated) START	$t_{SU:STA}$		600			ns
Data Hold Time	$t_{HD:DAT}$		0			ns
Data Setup Time	$t_{SU:DAT}$		100			ns

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Electrical Characteristics (continued)

(V_{IN} = 3.3V, V_{INN} = 3.3V, Limits are 100% guaranteed between T_A = -40°C and T_A = +125°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Setup Time for STOP Condition	$t_{SU:STO}$		600			ns
Spike Suppression				50		ns

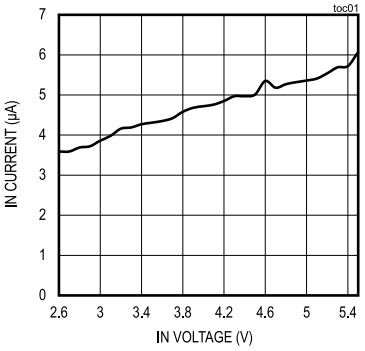
Note 1: Note 1: Limits are 100% tested at T_A = +25°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.

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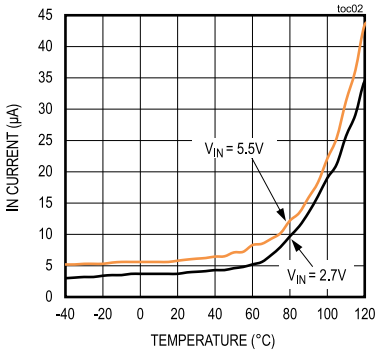
Typical Operating Characteristics

(V_{IN} = +3.3V, f_{SW} = 2.1MHz, T_A = +25°C unless otherwise noted.)

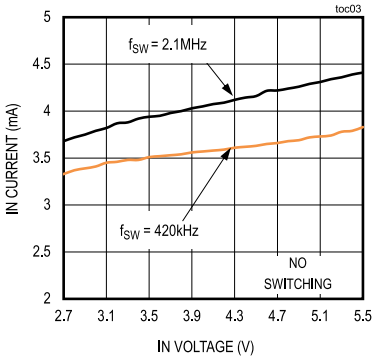
SHUTDOWN SUPPLY CURRENT



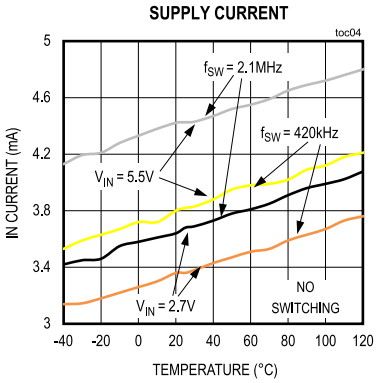
SHUTDOWN SUPPLY CURRENT



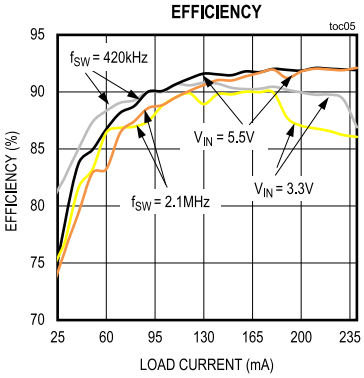
SUPPLY CURRENT



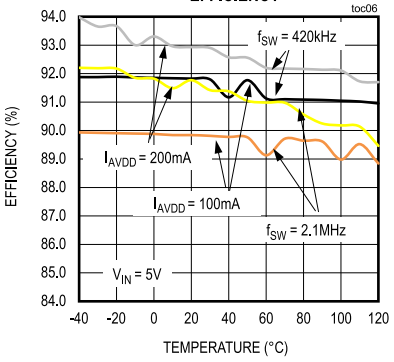
SUPPLY CURRENT



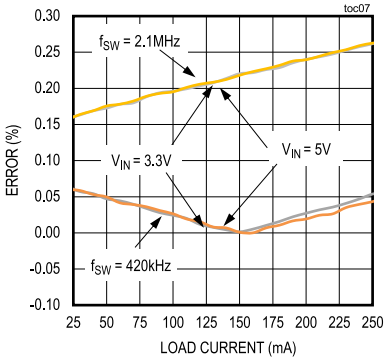
BOOST REGULATOR EFFICIENCY



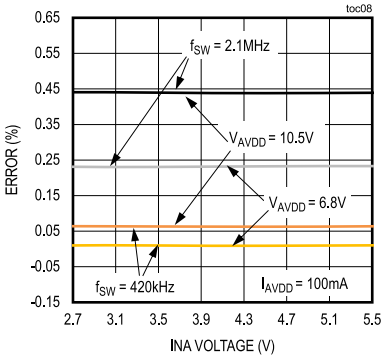
BOOST REGULATOR EFFICIENCY



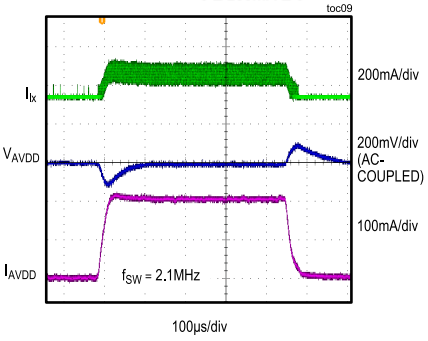
AVDD REGULATOR LOAD REGULATION



AVDD REGULATOR LINE REGULATION



AVDD REGULATOR LOAD STEP 0 ≥ 200mA ≥ 0

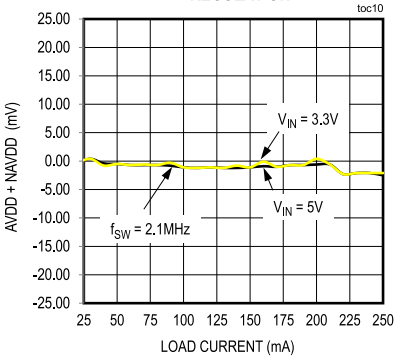


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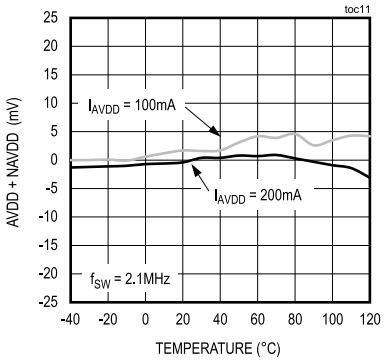
Typical Operating Characteristics (continued)

(V_{IN} = +3.3V, f_{SW} = 2.1MHz, T_A = +25°C unless otherwise noted.)

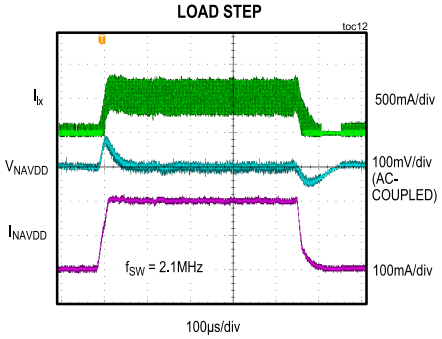
AVDD + NAVDD REGULATION



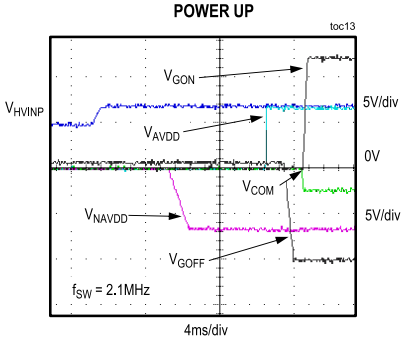
AVDD + NAVDD REGULATION



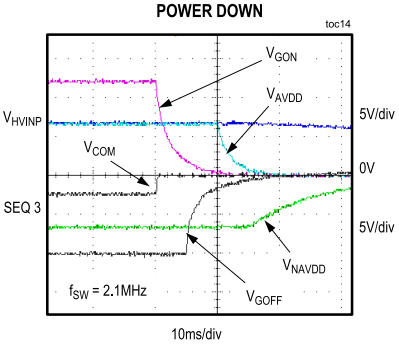
NAVDD REGULATOR LOAD STEP



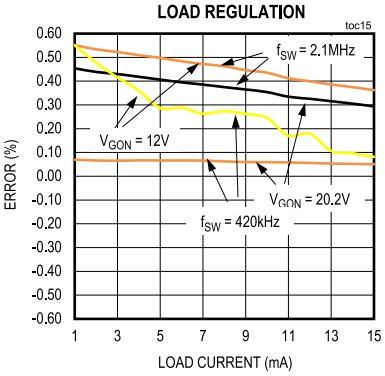
SUPPLY SEQUENCING WAVEFORM POWER UP



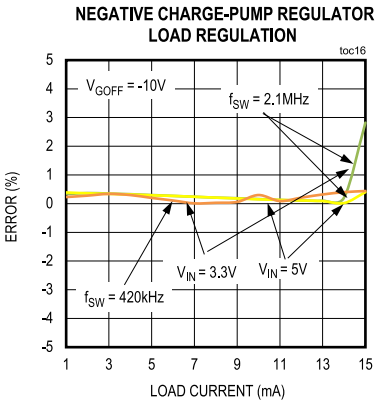
SUPPLY SEQUENCING WAVEFORM POWER DOWN



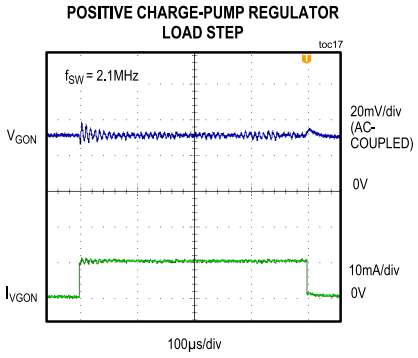
POSITIVE CHARGE-PUMP REGULATOR LOAD REGULATION



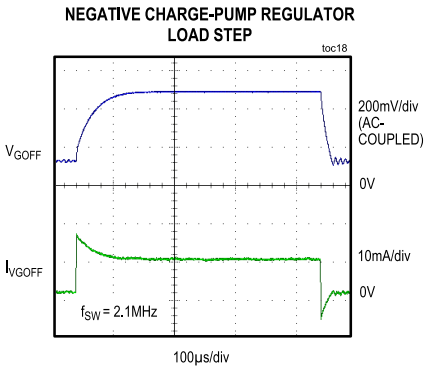
NEGATIVE CHARGE-PUMP REGULATOR LOAD REGULATION



POSITIVE CHARGE-PUMP REGULATOR LOAD STEP



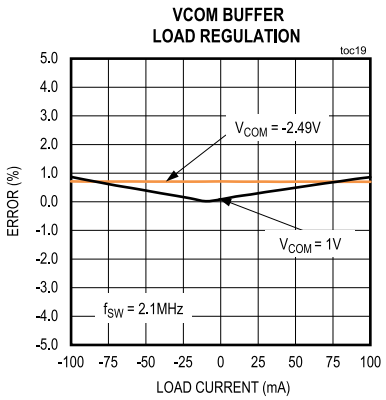
NEGATIVE CHARGE-PUMP REGULATOR LOAD STEP

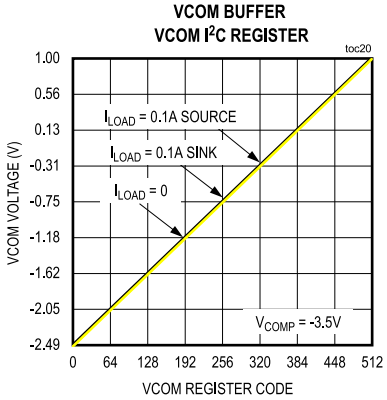


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Typical Operating Characteristics (continued)

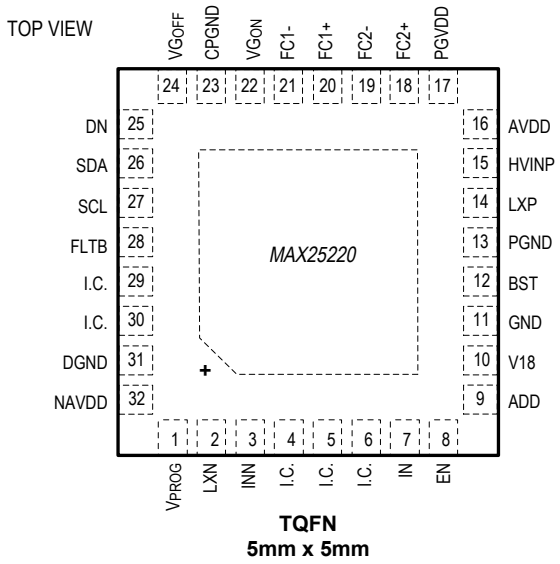
(V_{IN} = +3.3V, f_{SW} = 2.1MHz, T_A = +25°C unless otherwise noted.)





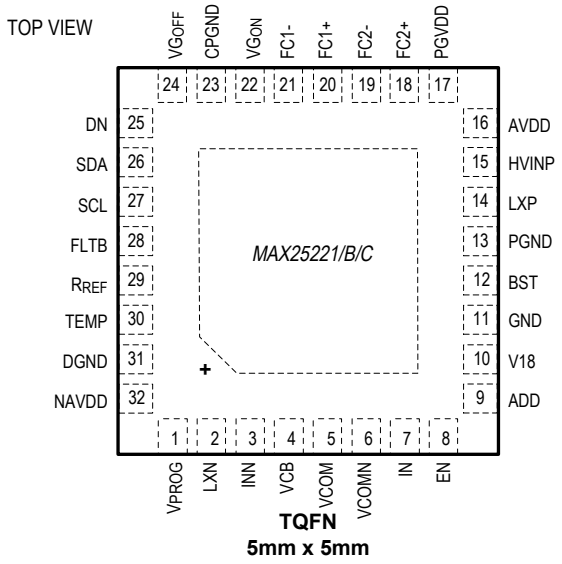
Pin Configurations

MAX25220



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MAX25221/B/C



Pin Description

PIN		NAME	FUNCTION
MAX25220	MAX25221/ B/C		
1	1	V_{PROG}	Programming Voltage. Apply a voltage of 8.5V to this pin during the programming of nonvolatile registers. Connect to GND through a resistor during normal operation.
2	2	LXN	DC-DC Inverting Converter Inductor/Diode Connection
3	3	INN	Inverting Converter Input. Connect 10µF + 0.1µF ceramic capacitors from this pin to ground for proper operation.
4	—	IC	Internally Connected. Leave this pin open.
—	4	VCB	Drive Output for External npn Pass Transistor for VCOMN Regulator. Connect to the base of the external npn transistor.
5	—	IC	Internally Connected. Leave this pin open.
—	5	VCOM	Output of VCOM Amplifier
6	—	IC	Internally Connected. Connect this pin to GND.
—	6	VCOMN	Negative Supply for VCOM Buffer. Connect a ceramic capacitor of at least 1µF from VCOMN to GND.
7	7	IN	Supply Connection for Display Bias Circuitry. Bypass IN with local 10µF and 0.1µF capacitors.

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Pin Description (continued)

PIN		NAME	FUNCTION
MAX25220	MAX25221/ B/C		
8	8	EN	Enable Input Pin. When EN is low, the device is in shutdown. When EN is taken high, the device is active. In standalone mode, the outputs are turned on in the stored sequence when EN goes high.
9	9	ADD	Device Address Select pin. Connect to GND or V18 to select the device I^2C address. See Table 5. To use standalone mode (without I^2C), leave the ADD pin open. In this mode, the device turns on all outputs in the programmed sequence when EN is taken high.
10	10	V18	Output of Internal 1.8V Regulator. Connect a 1µF capacitor from V18 to GND.
11	11	GND	Ground Connection
12	12	BST	Bootstrap Capacitor Connection for Synchronous Rectifier Driver. Connect a 0.1µF ceramic capacitor between BST and LXP.
13	13	PGND	Ground Connection for Boost Switching Device and VCOM Buffer. Connect to GND using a low-impedance trace.
14	14	LXP	Switching Node of Boost Converter. Connect the boost inductor between LXP and IN.
15	15	HVINP	Boost Output and Input to Positive and Negative Charge-Pump Drivers. Bypass HVINP with a 10µF output capacitor placed close to the pin.
16	16	AVDD	Switched Output of Boost Converter. Connect a bypass capacitor of value 2.2µF from AVDD to PGND.
17	17	PGVDD	Supply Voltage for Positive Charge Pump. PGVDD is connected to HVINP by means of an internal switch when the positive charge pump is enabled. Bypass PGVDD with a ceramic capacitor of 1µF to GND.
18	18	FC2+	Positive Connection for Second Flying Capacitor. Connect a 22nF capacitor from FC2- to FC2+.
19	19	FC2-	Negative Connection for Second Flying Capacitor. Connect a 22nF capacitor from FC2- to FC2+.
20	20	FC1+	Positive Connection for First Flying Capacitor. Connect a 22nF capacitor from FC1- to FC1+.
21	21	FC1-	Negative Connection for First Flying Capacitor. Connect a 22nF capacitor from FC1- to FC1+.
22	22	VG_{ON}	Output of Positive Charge-Pump Block. Connect a 1µF capacitor from VG_{ON} to GND.
23	23	CPGND	Ground Connection for Charge Pumps
24	24	VG_{OFF}	Output of Negative Charge-Pump Block. Connect a 1µF capacitor from this pin to GND.
25	25	DN	Negative Charge-Pump Push-Pull Drive Output
26	26	SDA	Bidirectional I^2C Data Pin
27	27	SCL	I^2C Clock Pin
28	28	FLTB	Open-Drain, Active-Low Fault Output. Connect a pull-up resistor from FLTB to a logic supply ≤5V. In standalone mode, the duty cycle of the FLTB pin indicates an error condition, if present (see Table 4). When the serial interface is used, FLTB is either a 0 (indicating data to be read from the internal registers) or a 1.
29	—	IC	Internally Connected. Leave this pin open.
—	29	R_{REF}	Reference Resistor Pin. When using the temperature compensation function, connect a resistor from R_{REF} to GND. If unused, leave R_{REF} unconnected.

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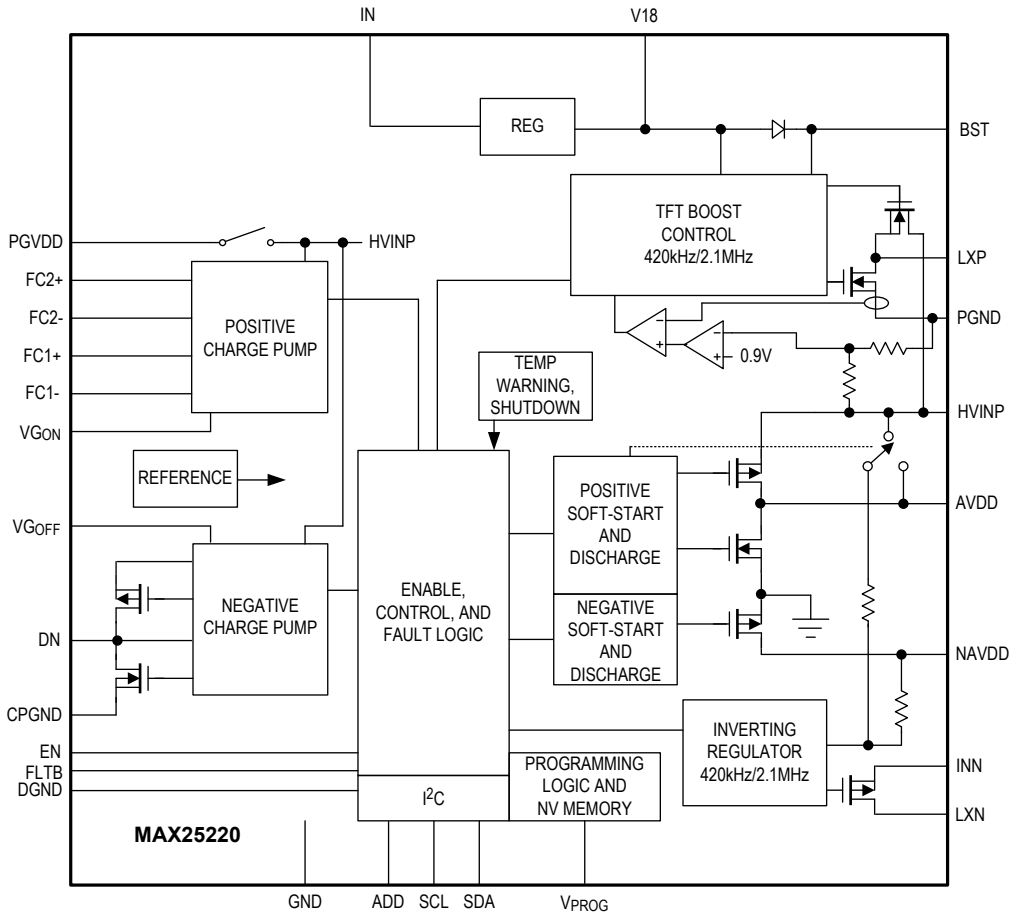
Pin Description (continued)

PIN		NAME	FUNCTION
MAX25220	MAX25221/ B/C		
30	—	IC	Internally Connected. Leave this pin open.
—	30	TEMP	Temperature Sensor Pin. When using the temperature compensation function, connect an NTC from TEMP to GND. If unused, leave TEMP unconnected.
31	31	DGND	Logic Ground.
32	32	NAVDD	Negative Source-Driver Output Voltage. Connect ceramic capacitors of value 0.1µF and 10µF from this pin to GND with the smallest capacitor closest to the pin.

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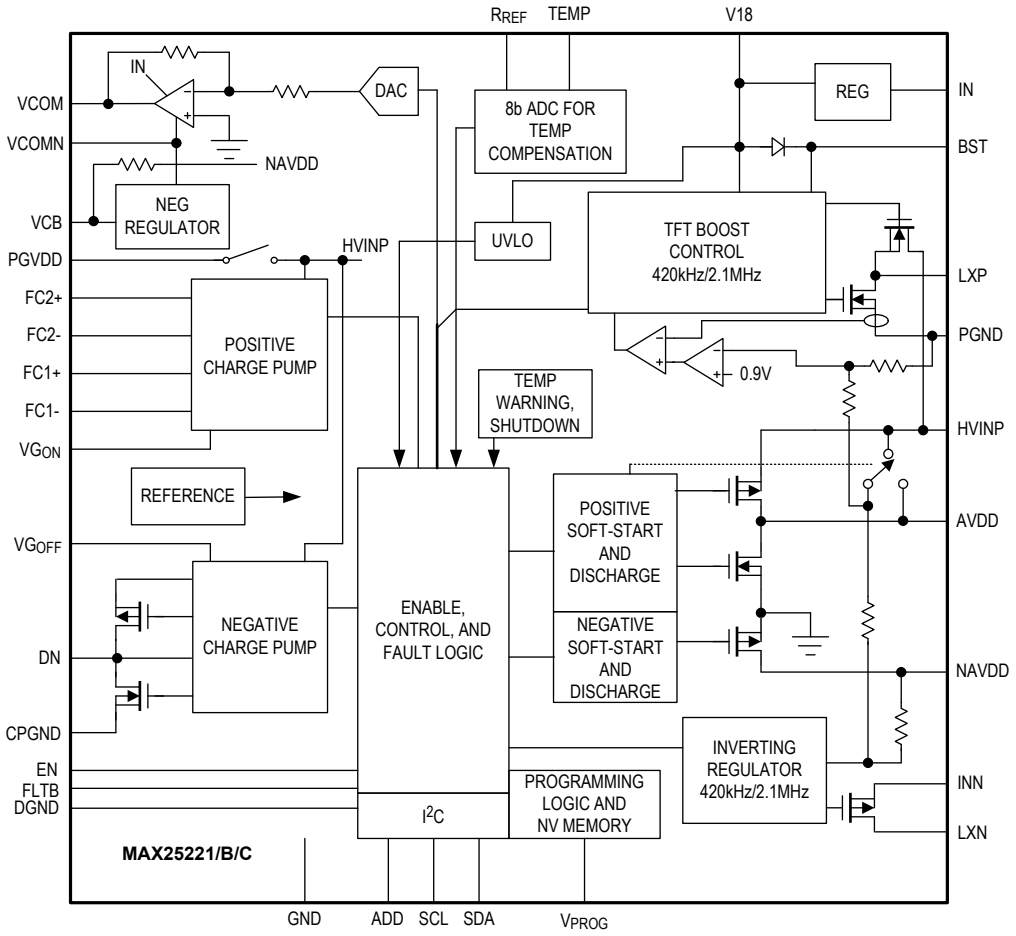
Functional Diagrams

MAX25220



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MAX25221/B/C



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Detailed Description

The MAX25220/MAX25221/MAX25221B/MAX25221C are 4-channel TFT-LCD power ICs that provide symmetrical positive AVDD and negative NAVDD supplies as well as VG_{ON} and VG_{OFF} gate supplies. In addition, a VCOM buffer with output voltage range above and below ground and a temperature-measurement block are integrated in the MAX25221, MAX25221B, and MAX25221C.

The devices contain nonvolatile memory so that the values of all outputs can be calibrated for the lifetime of the device.

Programming is carried out using the built-in I^2C interface, which can also be used to read back diagnostic information. Operation in standalone mode is also possible.

The temperature-sensor interface block in the MAX25221, MAX25221B, and MAX25221C determines the temperature by measuring the voltage on the R_{REF} pin when a temperature-sensitive component, such as an NTC, is connected to TEMP. The VCOM output voltage can be adjusted as a function of the measured temperature.

Power-Up State

When power is applied, the MAX25220/21/21B/21C are in low-quiescent-current mode until the EN pin is taken high. When EN is taken high (if the device supply voltage on IN exceeds the undervoltage lockout voltage of 2.5V) the 1.8V regulator is turned on and the device is functional after a delay of 1ms. Subsequent operation depends on the device configuration and type as follows:

Table 1. Device Behavior after Startup

DEVICE	ADD = 0	ADD PIN FLOATING	ADD = V18
MAX25220/1	Outputs turned on when start bit in register REG_CTRL is written to 1.	Outputs turned on immediately when EN high.	Outputs turned on when start bit in register REG_CTRL is written to 1.
MAX25221B/C	Outputs turned on immediately when EN high.	Outputs turned on immediately when EN high.	Outputs turned on immediately when EN high.

If the nonvolatile memory has been written to previously the stored values are read and the outputs are turned on in the programmed sequence. If the device has not been programmed previously it powers up with the default voltages of 6.8V (AVDD), 12V (VG_{ON}) and -10V (VG_{OFF}).

When I^2C is used, all values can be programmed and the outputs turned on using the start bit in the REG_CTRL register. The values can subsequently be stored in nonvolatile memory using the burn_otp command, if required.

If at any time the internal 1.8V regulator is out of range, the v18oor bit is set in register FAULT2 and the FLTB pin is asserted low, assuming the device is being used in I^2C mode. No other action is taken unless the V18 voltage is below its undervoltage lockout level.

Switching Frequency

The switching frequency of the boost and inverting converters and the charge pumps is set using the f_{SW} bit in register CONFIG. When f_{SW} is 0, the switching frequency is 2.1MHz. When f_{SW} is set to 1, the switching frequency is 420kHz. The switching frequency can have spread-spectrum applied to improve EMI performance using the en_ss bit in register CONFIG.

Standalone Operation

Standalone operation is used when the device has already been programmed and should start up with the preprogrammed values when power is applied and the EN pin taken high. In standalone mode, leave the ADD pin unconnected.

I^2C Read-Only Mode

The MAX25221B/C starts up immediately with the preprogrammed values when power is applied and the EN pin taken high. If the ADD pin is connected to V18, the I^2C interface is in read-only mode and can only be used to read the device registers—writing is not possible. The 7-bit I^2C address of the device is 0x29 (0x53 when the read bit is added) in this

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mode.

Source Driver Power Supplies

The source-driver power supplies consist of a boost converter with an output switch and an inverting buck-boost converter that generate up to +10.5V maximum and down to -10.5V minimum, respectively, and can deliver up to 200mA on the positive regulator and -200mA on the negative regulator. The positive source-driver power supply's regulation voltage (AVDD) is set by writing the avdd[5:0] value in the AVDD_SET register using the I^2C interface, and can be programmed into nonvolatile memory. The default AVDD output voltage is 6.8V.

The negative source-driver supply voltage (NAVDD) is automatically tightly regulated to -AVDD within ±34mV. NAVDD cannot be adjusted independently of AVDD.

The AVDD boost converter is a current-mode converter with two internal switches and internal compensation. The direct output of the converter is HVINP while AVDD is a switched-output version. The NAVDD converter is a current-mode converter with one internal switch, an external diode and internal compensation.

Gate-Driver Power Supplies

The positive gate-driver power supply (VG_{ON}) is a regulated charge-pump tripler and generates up to +20.2V. Note also that the maximum output voltage is 3 x AVDD - $R_{ONTOTAL}$ x I_{VGON} x K, where $R_{ONTOTAL}$ is typically 30Ω and K is a factor 0.75. In cases where a doubler charge pump is sufficient, set the cp_2stage bit and leave pins FC1- and FC1+ unconnected in order to increase efficiency.

The negative gate-driver power supply (VG_{OFF}) generates a maximum negative voltage of -18.2V and requires external diodes and capacitors. The VG_{ON} and VG_{OFF} blocks switch at the same frequency as the AVDD and NAVDD converters.

Both supplies are capable of output currents up to 15mA, assuming sufficient headroom. The VG_{ON} and VG_{OFF} regulation voltages are set by writing the vgon[5:0] and vgoff[5:0] values in the register map using the I^2C interface, and can be stored in the nonvolatile section of the register map.

Sequencing

The power-on and power-off sequences are controlled by the seq_set[2:0] bits in the VCOM_L register. The setting should be written before the sequence is to be executed and should not be changed during the turn-on or turn-off sequences. The sequence options are as follows:

Table 2. Available Sequences

	SEQUENCE SET BITS			POWER-ON				POWER-OFF (REVERSE-ORDER OF POWER-ON)				NOTES
Sequence No.	**seq_set2**	**seq_set1**	**seq_set0**	**1st**	**2nd after t1 ms**	**3rd after t2 ms**	**4th after t3 ms**	1st	2nd after t3 ms	3rd after t2 ms	4th after t1 ms	
1	0	0	0	AVDD	NAVDD	VG_{OFF}	VG_{ON}/ VCOM	VG_{ON}/ VCOM	VG_{OFF}	NAVDD	AVDD	
2	0	0	1	AVDD	NAVDD	VG_{ON}	VG_{OFF}/ VCOM	VG_{OFF}/ VCOM	VG_{ON}	NAVDD	AVDD	
3	0	1	0	NAVDD	AVDD	VG_{OFF}	VG_{ON}/ VCOM	VG_{ON}/ VCOM	VG_{OFF}	AVDD	NAVDD	Default setting
4	0	1	1	NAVDD	AVDD	VG_{ON}	VG_{OFF}/ VCOM	VG_{OFF}/ VCOM	VG_{ON}	AVDD	NAVDD	
5	1	0	0	NAVDD	VG_{OFF}	AVDD	VG_{ON}/ VCOM	VG_{ON}/ VCOM	AVDD	VG_{OFF}	NAVDD	
6	1	0	1	VG_{OFF}	VG_{ON}	NAVDD	AVDD/ VCOM	AVDD/ VCOM	NAVDD	VG_{ON}	VG_{OFF}	
7	1	1	0	AVDD/ NAVDD	VG_{OFF}	VG_{ON}/ VCOM	—	VG_{ON}/ VCOM	VG_{OFF}	AVDD/ NAVDD	—	

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Table 2. Available Sequences (continued)

8	1	1	1	AVDD/ NAVDD	VG_{ON}	VG_{OFF}/ VCOM	—	VG_{OFF}/ VCOM	VG_{ON}	AVDD/ NAVDD	—	

The times in Table 2 are determined by the delayt1, delayt2 and delayt3 settings in the DELAY-VCOM_LSB register. The fastest power-up is obtained by setting the delays to 0.

The output voltages are not monitored during off sequencing; each output is turned off in turn using the programmed delays. When the delays are set to zero, outputs are turned off in sequence with 1ms delays. A sequence can be stored in nonvolatile memory by writing to the burn_otp_reg register.

The V18 linear regulator is powered down 200ms after the power-down sequence is complete. After this time, the device is in shutdown mode and can be restarted by setting the EN input high.

Sequencing Diagram

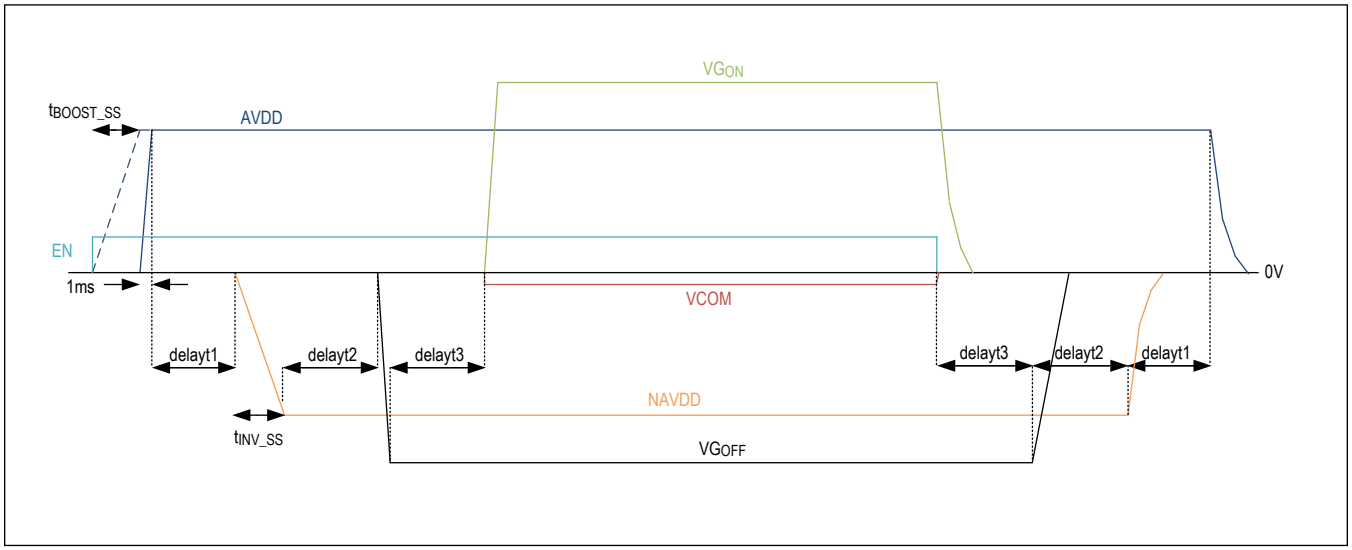


Figure 1. Sequencing Example (Sequence 1, Not to Scale)

VCOM Buffer

The VCOM output voltage is programmed using I^2C to a value between -2.49V and +1V. The 9-bit value can also be stored in nonvolatile memory. The most-significant bits of the VCOM voltage setting are in the VCOM25 register while the least-significant bit is the vcom25_0 bit in the DELAY-DELAYVCOM_LSB register.

The VCOM buffer can output peak currents up to ±120mA. If the VCOM output voltage deviates from the set value by more than 0.25V, a VCOM fault is detected and flagged with the vcom_flt bit in the FAULT2 register. When this fault is detected, the VCOM buffer continues to function—it is not automatically disabled. Note that a fault condition can lead to high power dissipation in the VCOM buffer and could lead to thermal shutdown of the entire device. If the VCOM buffer is continuously in current limit for more than the time set by tfault[1:0], it is disabled together with the AVDD, NAVDD, VG_H and VG_L outputs to avoid damage to the IC. Also in this case the vcom_flt bit is set.

The maximum capacitive load on the VCOM output is 10nF. If higher capacitance loads are used, a series resistor should be employed to maintain stability.

To calculate the value to write to the VCOM25 register use the following equation:

$$VCOM25 = \frac{V_{COM} + 2.49}{0.00683}$$

The correspondence between the VCOM set value and the VCOM voltage is shown in Table 3.

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Table 3. VCOM Settings

VCOM25 REGISTER VALUE	VCOM VOLTAGE (V)
0x1FF	1
0x1FE	0.9932
...	...
0x16E	+0.0098
0x16D	+0.003
0x16C	-0.0039
...	...
0x002	-2.4763
0x001	-2.4832
0x000	-2.49

VCOMN Negative Power Supply

A linear regulator is implemented to derive a regulated -3.5V for the VCOM buffer from the NAVDD supply.The npn transistor connected to the VCB pin acts as the pass transistor of the regulator. The peak output current of the regulator is the same as the peak negative drive current from the VCOM output, or at least 120mA. The device senses the voltage at VCOMN and regulates it to -3.5V by driving VCB. The peak drive current for the base of the external npn is at least 5mA.

Limiting the Range of VCOM Voltage

When temperature compensation is not enabled, it is possible to limit the excursion of VCOM to a range between the values set in the VCOM_MIN and VCOM_MAX registers. If an attempt is made to write a value outside the set range to VCOM25, the VCOM output voltage is not updated and the I^2C interface issues a NACK.

VCOM Temperature Compensation

The VCOM output voltage can be compensated for temperature changes using a temperature-sensitive component (e.g. an NTC thermistor) connected to the TEMP input or an internal temperature sensor. Select the sensor to be used with the int_sensor bit in the CONFIG register (the default configuration is to use the external sensor). The TEMP pin is forced to 625mV and the current drawn from it is mirrored on the R_{REF} pin. The voltage generated due to the resistor on R_{REF} is fed to the internal 8-bit ADC, which has a reference voltage of 1.25V. The input to the ADC is therefore as follows:

$$V_{ADC} = \frac{0.625 \times R_{RREF}}{R_{TEMP}}$$

With reference to Figure 2: $R_{TEMP} = (R_{NTC} \mid\mid R1) + R2$

The highly non-linear NTC characteristic can be modified depending on which temperature (cold, room, or hot) necessitates the highest resolution. As an example in Figure 2, a reference resistor is connected to R_{REF} while a combination of the NTC and two low-TC resistors R1 and R2 are connected to TEMP. In this way, an ADC reading that is steeper at higher temperatures is obtained, enhancing the resolution of the ADC there. When temperature compensation is enabled, the value of the voltage on the R_{REF} pin is available in the TEMP (0x01) register.

Temperature compensation is enabled by setting the T_comp_en bit in the DELAY-VCOM_LSB register. When T_comp_en is high, the voltage on the R_{REF} pin is measured and the VCOM output voltage is updated at a rate of 1Hz. At start-up, even with temperature compensation enabled, there is a delay before compensation becomes active due to the time needed to sample the temperature. For this reason, the device always starts up with the VCOM25 voltage value on VCOM.

The VCOM value at +25°C is the value written in the VCOM25 register together with the LSB from DELAY-VCOM_LSB register. This value serves as the reference for all other VCOM values. The 5-bit values in the VCOM_L, and VCOM_H1 registers represent the change in VCOM from the VCOM25 value at the temperature represented by an ADC reading of VTEMP_L and VTEMP_H1. The value in the VCOM_H2 register represents the positive shift in VCOM from VCOM_H1. The VCOM_L value represents a negative shift in VCOM while VCOM_H1 and VCOM_H2 represent positive shifts.

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NTC Connection Diagram

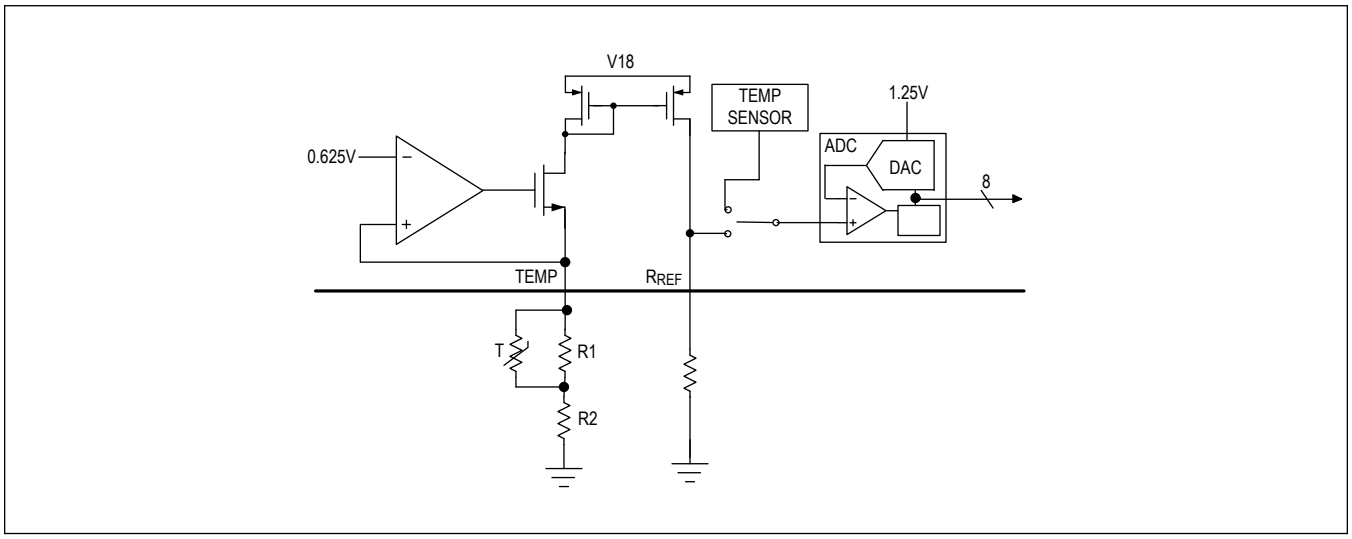


Figure 2. Possible NTC Connection

Internal Temperature Sensor

The internal temperature sensor senses the junction temperature of the IC which may be significantly different from the ambient temperature. To use the internal sensor, set the int_sensor bit in the CONFIG register to 1. The internal temperature sensor has a temperature coefficient of 2mV/°C and a nominal output voltage of 620mV at +25°C.

When the internal temperature sensor is selected, it is connected directly to the ADC input.

Temperature Compensation Curve

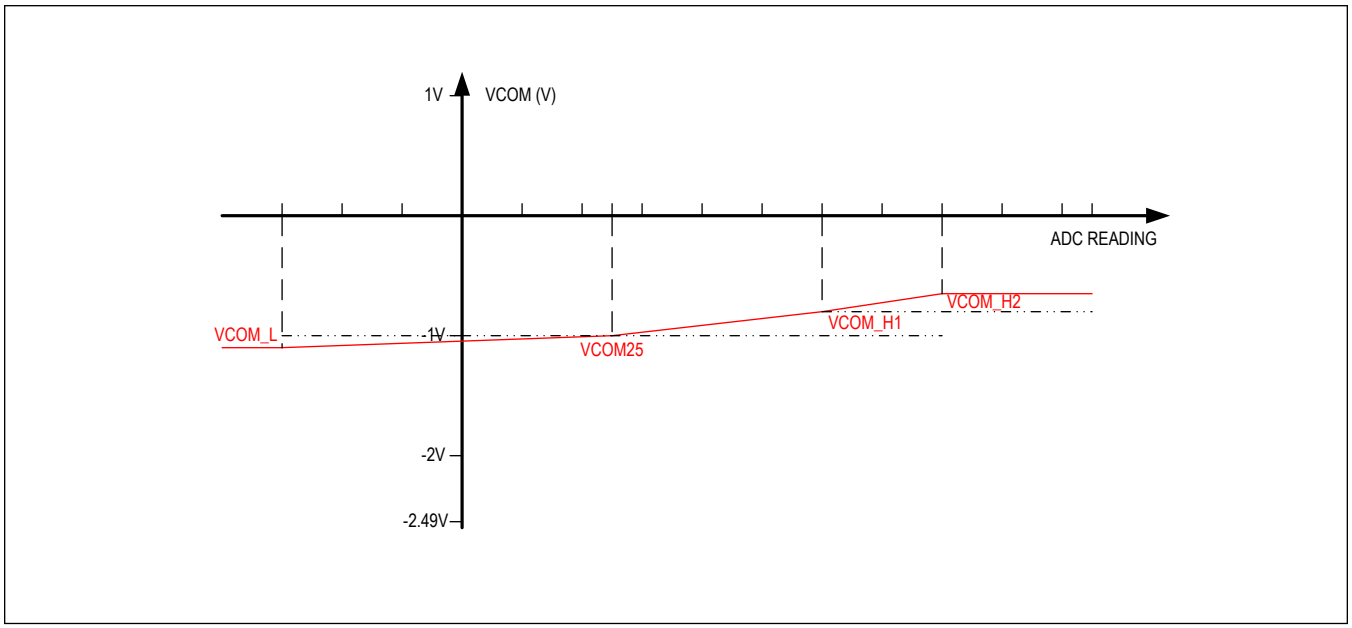


Figure 3. Temperature Compensation Curve

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Fault Handling

The reaction to faults is dependent on whether the device is in I²C or standalone mode.

In I²C mode, the following faults, if not masked, cause the FLTB pin to assert low: avdd_uv, navdd_uv, vgon_uv, vgoff_uv, vcom_flt, nv_flt, th_shdn, vin_uvlo, and par_err. The th_warn fault is masked by default and must be explicitly enabled using the th_warn_mask bit.

When the ADD pin is left floating (I²C interface not used), the FLTB pin outputs a pulse train of varying duty cycle depending on the detected fault as shown in Table 4.

Table 4. FLTB Duty Cycle in Standalone Mode

DUTY-CYCLE	FAULT
75%	VG_{ON} or VG_{OFF} fault
50%	AVDD, NAVDD, or HVINP fault
25%	VCOM fault
0% (continuously low)	NV fault or thermal shutdown

The frequency at the FLTB pin is 1kHz when indicating a fault. If multiple faults are present, the highest-priority fault is indicated. The Table 4 list is in order of priority with the highest priority listed last.

Undervoltage Faults on Source and Gate Outputs

When an undervoltage is detected on any of the AVDD, NAVDD, VG_{ON}, or VG_{OFF} outputs, all of the outputs are turned off and the appropriate fault bit is set in the FAULT1 register. At the same time, the FLTB pin asserts low. Depending on the setting of the tretry[1:0] bits, the subsequent behavior of the device is as follows:

- tretry = 01, 10 or 11: After 0.95s or 1.9s a retry is performed where all outputs are turned on in the appropriate sequence. If the fault is still present, the output will be disabled again after tfault[1:0]. A total of three retries are performed, after which no further retry attempts are performed (the device can be restarted by toggling power or the EN pin or by using the RESTART command). If tretry = 11 retries continue until the fault is removed and normal function can resume.
- tretry = 00: No retry is attempted (the device can be restarted by toggling power or the EN pin or by using the RESTART command).

If a short-circuit is encountered during start-up, device operation is halted, all outputs are disabled, and the subsequent behavior depends on the setting of retry[1:0] as described above. The short-circuit checks on VG_{ON} and VG_{OFF} are enabled 1ms after the pins are enabled. The C version does not have short-circuit checks on VG_{ON} and VG_{OFF}.

During retry, faults are no longer monitored and the fault or faults which caused retry are indicated using the corresponding fault bits. During retry, the FLTB pin asserts low unless the fault which caused the retry is masked.

Thermal Warning and Shutdown

When the junction temperature reaches +125°C, the thermal warning bit is set. The device takes no further action.

If the device junction temperature reaches +160°C, all outputs are turned off immediately. When the junction temperature drops by 15°C, the outputs are reenabled using the stored sequence.

NV Memory

The MAX25220/MAX25221/MAX25221B/MAX25221C include six blocks of one-time-programmable memory (the number of writes performed so far can be read from nv_count[2:0] in the REG_CTRL register). The user can store the block of volatile registers from 0x07 to 0x15 in nonvolatile memory, which is in turn mapped to register locations 0x17 to 0x25. Note that before the nonvolatile memory has been programmed, a read from the locations 0x17 to 0x25 yields the result 0xFF.

The contents of the nonvolatile memory are protected by a single-error correction/double-error detection (SECDED) redundant code while data transfer from nonvolatile memory to registers 0x07 to 0x15 is protected by a parity check. If the parity check fails, a retry is performed two times. If all three attempts are unsuccessful, the device does not start up, the nv_flt bit is set, and the FLTB pin is asserted low. If the SECDED check fails, the device does not start up, the nv_flt bit is set, and the FLTB pin is asserted low.

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If there are no errors, the outputs are turned on with the stored values and in the stored sequence.

To store the contents of registers 0x07 to 0x15 to nonvolatile memory a voltage source of 8.5V ±2% capable of supplying more than 25mA should be connected to the V_{PROG} pin. When the V_{PROG} voltage is stable an I^2C NV write command can be performed by writing to the burn_otp_reg register. If the NV write is unsuccessful (because the V_{PROG} voltage was out of range or because of a general memory error) the nv_flt bit is set, FLTB pin goes low. After an NV write command is executed, the nv_flt bit should be checked. If nv_flt is high another NV write can be attempted.

Connect V_{PROG} to GND if nonvolatile memory is not used.

Ensure that temperature compensation is disabled when programming VCOM.

Auto-Refresh Function

When the refresh bit in register CONFIG is set, the device reads from the nonvolatile registers at intervals of 1s and writes the data into the corresponding volatile registers. This avoids the effect of possible corruption of the volatile registers. Auto-refresh reads are subject to error correction in the same way as the initial read after device power-up.

When programming the nonvolatile memory, the auto-refresh function should be enabled immediately before performing the burn_otp_reg write. See the *Using the NV Memory* section in *Applications Information*.

BURN, REBOOT, and RESTART Commands

The BURN and REBOOT commands are used to store the contents of registers 0x07 to 0x15 in nonvolatile memory or to fetch the contents of nonvolatile memory and load them into registers 0x07 to 0x15, respectively. The RESTART command is used to restart the device from a latched-fault mode. When a RESTART command is performed, all fault bits are cleared.

A BURN command is performed by writing to register address 0x78 (burn_otp_reg).

A REBOOT command is performed by writing to register address 0x79 (reboot_otp_reg).

A RESTART command is performed by writing to register address 0x7A (soft_restart).

When parity checking is enabled and one of these user commands is sent to the device, the third byte should be such as to have even parity over the 3 bytes sent.

I^2C Interface

The MAX25220/MAX25221/MAX25221B/MAX25221C include an I^2C, 2-wire serial interface consisting of a serial-data line (SDA) and a serial-clock line (SCL). SDA and SCL facilitate communication between the IC and the controller at clock rates up to 400kHz. The controller, typically a microcontroller, generates SCL and initiates data transfer on the bus.

The Target ID of the MAX25220/MAX25221/MAX25221B/MAX25221C depends on the connection of the ADD pin according to Table 5.

A controller device communicates with the MAX25220/MAX25221/MAX25221B/MAX25221C by transmitting the correct Target ID with appended R/W bit, followed by the register address and data word (for a write transaction only). Each transmit sequence is framed by a START (S) or Repeated START (Sr) condition, and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge clock pulse.

The IC's SDA line operates as both an input and an open-drain output. A pull-up resistor greater than 1kΩ is required on the SDA bus. In general, the resistor should be selected as a function of bus capacitance such that the rise time on the bus is not greater than 120ns. The IC's SCL line operates as an input only. A pull-up resistor greater than 1kΩ is required on SCL if there are multiple controllers on the bus, or if the controller in a single-controller system has an open-drain SCL output. In general, for the SCL-line resistor selection, the same recommendations as for SDA apply. Series resistors in line with SDA and SCL are optional. The SCL and SDA inputs suppress noise spikes to assure proper device operation even on a noisy bus.

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I²C Target Addresses

Table 5. I²C Target Addresses

ADD PIN CONNECTION	DEVICE ADDRESS							WRITE ADDRESS	READ ADDRESS
	A6	A5	A4	A3	A2	A1	A0		
GND	0	1	0	0	0	0	1	0x42	0x43
V18	0	1	0	1	0	0	1	0x52*	0x53

* On the MAX25221B/C, writing to the device is not possible when ADD is connected to V18.

Parity Checking

Even parity checking for write transactions can be enabled by setting the par_en bit in REG_CTRL to 1. The parity bit is the most-significant bit of the register address byte and should be set to attain even parity. The parity check is performed over all 3 bytes received by the device: the target address, the register address, and the data payload. Burst-mode write is not supported when parity checking is enabled; a complete I²C transaction is needed to write to each single register. When a parity bit error is detected the par_err bit is set, the I²C interface issues a NACK and no write is performed.

When writing any of the BURN, REBOOT, and RESTART commands, parity must be adjusted by changing the third or payload byte; the command byte must not be changed.

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Register Map

MAX25220/MAX25221/MAX25221B/MAX25221C

ADDRESS	NAME	MSB							LSB
USER REGISTERS									
0x00	DEVICE[7:0]	–	–	dev_id[5:0]					
0x01	TEMP[7:0]	temp[7:0]							
0x02	REG_CTRL[7:0]	par_en	start	nv_count[2:0]			rev_id[2:0]		
0x03	FLTMASK1[7:0]	–	avdd_uv_mask	–	navdd_uv_mask	–	vgon_uv_mask	–	vgoff_uv_mask
0x04	FLTMASK2[7:0]	–	par_err_mask	vin_uvlo_mask	hvinp_uv_mask	–	–	vcom_flt_mask	th_warn_mask
0x05	FAULT1[7:0]	–	avdd_uv	–	navdd_uv	–	vgon_uv	–	vgoff_uv
0x06	FAULT2[7:0]	v18oor	par_err	vin_uvlo	hvinp_uv	th_shdn	nv_flt	vcom_flt	th_warn
0x07	CONFIG[7:0]	int_sensor	refresh	en_ss	fSW	tretry[1:0]		tfault[1:0]	
0x08	DELAY-VCOM_LSB[7:0]	delayt1[1:0]		delayt2[1:0]		delayt3[1:0]		T_comp_en	vcom25_0
0x09	VCOM25[7:0]	vcom25[7:0]							
0x0A	VCOM_L[7:0]	seq_set[2:0]			vcom_l[4:0]				
0x0B	VCOM_H1[7:0]	–	–	–	vcom_h1[4:0]				
0x0C	VCOM_H2[7:0]	–	–	–	vcom_h2[4:0]				
0x0D	VTEMP25[7:0]	vtemp25[7:0]							
0x0E	VTEMP_L[7:0]	vtemp_l[7:0]							
0x0F	VTEMP_H1[7:0]	vtemp_h1[7:0]							
0x10	VTEMP_H2[7:0]	vtemp_h2[7:0]							
0x11	VCOM_MIN[7:0]	vcom_min[7:0]							
0x12	VCOM_MAX[7:0]	vcom_max[7:0]							
0x13	AVDD_SET[7:0]	–	–	avdd[5:0]					
0x14	VGON[7:0]	–	cp_2stage	vgon[5:0]					
0x15	VGOFF[7:0]	–	–	vgoff[5:0]					
0x17	NV_CONFIG[7:0]	nv_int_sensor	nv_refresh	nv_en_ss	nv_fSW	nv_retry[1:0]		nv_tfault[1:0]	
0x18	NV_DELAY-VCOM_LSB[7:0]	nv_delayt1[1:0]		nv_delayt2[1:0]		nv_delayt3[1:0]		nv_T_comp_en	nv_vcom25_0
0x19	NV_VCOM25[7:0]	nv_vcom25[7:0]							
0x1A	NV_VCOM_L[7:0]	nv_seq_set[2:0]			nv_vcom_l[4:0]				
0x1B	NV_VCOM_H1[7:0]	–	–	–	nv_vcom_h1[4:0]				
0x1C	NV_VCOM_H2[7:0]	–	–	–	nv_vcom_h2[4:0]				
0x1D	NV_VTEMP25[7:0]	nv_vtemp25[7:0]							
0x1E	NV_VTEMP_L[7:0]	nv_vtemp_l[7:0]							
0x1F	NV_TEMP_H1[7:0]	nv_vtemp_h1[7:0]							
0x20	NV_TEMP_H2[7:0]	nv_vtemp_h2[7:0]							

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ADDRESS	NAME	MSB							LSB
0x21	NV_VCOM_MIN[7:0]	nv_vcom_min[7:0]							
0x22	NV_VCOM_MAX[7:0]	nv_vcom_max[7:0]							
0x23	NV_AVDD_SET[7:0]	–	–	nv_avdd[5:0]					
0x24	NV_VGON[7:0]	–	nv_cp_2 stage	nv_vgon[5:0]					
0x25	NV_VGOFF[7:0]	–	–	nv_vgoff[5:0]					
USER COMMANDS									
0x78	burn_otp_reg[7:0]	burn_otp[7:0]							
0x79	reboot_otp_reg[7:0]	reboot_otp[7:0]							
0x7A	soft_restart[7:0]	soft_restart[7:0]							

Register Details

DEVICE (0x00)

BIT	7	6	5	4	3	2	1	0
Field	–	–	dev_id[5:0]					
Reset	–	–						
Access Type	–	–	Read Only					

BITFIELD	BITS	DESCRIPTION
dev_id	5:0	Device ID. Reads 0x20/21

TEMP (0x01)

BIT	7	6	5	4	3	2	1	0
Field	temp[7:0]							
Reset	0x0							
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
temp	7:0	Voltage reading from R_{REF} pin.

REG_CTRL (0x02)

BIT	7	6	5	4	3	2	1	0
Field	par_en	start	nv_count[2:0]			rev_id[2:0]		
Reset	0x0	0x0				0x1		
Access Type	Write, Read	Write, Read	Read Only			Read Only		

BITFIELD	BITS	DESCRIPTION
par_en	7	Parity enable bit. When 1 this bit enables parity checking on write transactions to the device.
start	6	Enable bit. When this bit is set to 1, the turn-on sequence set using the seq_set bits is executed. The default value of this bit is 0, except in the C version where it is 1.

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BITFIELD	BITS	DESCRIPTION
nv_count	5:3	This field indicates the total number of writes to nonvolatile memory. The maximum value is 6.
rev_id	2:0	Revision ID. Reads 0x1.

FLTMASK1 (0x03)

BIT	7	6	5	4	3	2	1	0
Field	–	avdd_uv_mask	–	navdd_uv_mask	–	vgon_uv_mask	–	vgoff_uv_mask
Reset	–	0x0	–	0x0	–	0x0	–	0x0
Access Type	–	Write, Read	–	Write, Read	–	Write, Read	–	Write, Read

BITFIELD	BITS	DESCRIPTION
avdd_uv_mask	6	When 1 this bit prevents an undervoltage on AVDD from asserting FLTB low.
navdd_uv_mask	4	When 1 this bit prevents an undervoltage on NAVDD from asserting FLTB low.
vgon_uv_mask	2	When 1 this bit prevents an undervoltage on VG_{ON} from asserting FLTB low.
vgoff_uv_mask	0	When 1 this bit prevents an undervoltage on VG_{OFF} from asserting FLTB low.

FLTMASK2 (0x04)

BIT	7	6	5	4	3	2	1	0
Field	–	par_err_mask	vin_uvlo_mask	hvinp_uv_mask	–	–	vcom_flt_mask	th_warn_mask
Reset	–	0x0	0x0	0x0	–	–	0x0	0x1
Access Type	–	Write, Read	Write, Read	Write, Read	–	–	Write, Read	Write, Read

BITFIELD	BITS	DESCRIPTION
par_err_mask	6	When 1 prevents parity errors from asserting the FLTB pin.
vin_uvlo_mask	5	When 1 this bit prevents an undervoltage on IN from asserting the FLTB pin.
hvinp_uv_mask	4	Mask bit for hvinp_uv diagnostic. When 1 an undervoltage on HVINP does not cause FLTB to assert.
vcom_flt_mask	1	When 1 this bit prevents a fault on VCOM from asserting FLTB low.
th_warn_mask	0	When 1 this bit prevents an overtemperature warning from asserting FLTB low.

FAULT1 (0x05)

BIT	7	6	5	4	3	2	1	0
Field	–	avdd_uv	–	navdd_uv	–	vgon_uv	–	vgoff_uv
Reset	–	0x0	–	0x0	–	0x0	–	0x0
Access Type	–	Read Clears All	–	Read Clears All	–	Read Clears All	–	Read Clears All

BITFIELD	BITS	DESCRIPTION
avdd_uv	6	When 1 this bit indicates an undervoltage on AVDD.
navdd_uv	4	When 1 this bit indicates an undervoltage on NAVDD.

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BITFIELD	BITS	DESCRIPTION
vgon_uv	2	When 1 this bit indicates an undervoltage on VG_{ON}.
vgoff_uv	0	When 1 this bit indicates an undervoltage on VG_{OFF}.

FAULT2 (0x06)

BIT	7	6	5	4	3	2	1	0
Field	v18oor	par_err	vin_uvlo	hvinp_uv	th_shdn	nv_flt	vcom_flt	th_warn
Reset	0x0	0x0	0x0	0x0	0x0	0x0	0x0	0x0
Access Type	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All

BITFIELD	BITS	DESCRIPTION
v18oor	7	Indicates that the 1.8V output is out of range, either above its overvoltage level or below its undervoltage level.
par_err	6	Indicates that a parity error was detected on an I^2C transaction.
vin_uvlo	5	Indicates an undervoltage condition on the IN pin. When this happens the device turns off all outputs and waits for IN to return above the IN UVLO level, after which the outputs are re-enabled in the programmed sequence.
hvinp_uv	4	When 1 this bit indicates an undervoltage on the boost output, HVINP.
th_shdn	3	When 1 this bit indicates an overtemperature shutdown.
nv_flt	2	Nonvolatile memory failure - unsuccessful transfer of the contents of NV memory to working memory or more than one error detected.
vcom_flt	1	When 1 indicates a fault on the VCOM output either due to it being 0.25V away from its set value (unfiltered) or because the VCOM buffer was in current limit for a time t_{fault}.
th_warn	0	When 1 this bit indicates a thermal warning.

CONFIG (0x07)

BIT	7	6	5	4	3	2	1	0
Field	int_sensor	refresh	en_ss	fSW	tretry[1:0]		tfault[1:0]	
Reset	0x0	0x0	0x0	0x0	0x1		0x0	
Access Type	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read		Write, Read	

BITFIELD	BITS	DESCRIPTION	DECODE
int_sensor	7	Set this bit to 1 to use the internal temperature sensor.	
refresh	6	When this bit is 1 the contents of the NV registers are automatically copied to the volatile registers every second.	0x0: Refresh disabled. 0x1: Refresh enabled.
en_ss	5	Enable spread-spectrum by setting this bit to 1.	
fSW	4	Sets switching frequency.	0x0: 2.1MHz 0x1: 420kHz
tretry	3:2	Sets retry time after a fault.	0x0: Retry disabled 0x1: Retry after 0.95s, total 3 retries. 0x2: Retry after 1.9s, total 3 retries. 0x3: Retry after 1.9s

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BITFIELD	BITS	DESCRIPTION	DECODE
tfault	1:0	Sets fault delay time.	0x0: 15ms 0x1: 30ms 0x2: 60ms 0x3: 90ms

DELAY-VCOM_LSB (0x08)

BIT	7	6	5	4	3	2	1	0
Field	delayt1[1:0]		delayt2[1:0]		delayt3[1:0]		T_comp_en	vcom25_0
Reset	0x2		0x2		0x2		0x0	0x0
Access Type	Write, Read		Write, Read		Write, Read		Write, Read	Write, Read

BITFIELD	BITS	DESCRIPTION
delayt1	7:6	Set delay t1 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.
delayt2	5:4	Set delay t2 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.
delayt3	3:2	Set delay t3 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.
T_comp_en	1	When 1 this bit enables temperature compensation of the output of the VCOM amplifier.
vcom25_0	0	LSB of VCOM setting at 25°C.

VCOM25 (0x09)

BIT	7	6	5	4	3	2	1	0
Field	vcom25[7:0]							
Reset	0x0							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vcom25	7:0	VCOM setting at 25°C.

VCOM_L (0x0A)

BIT	7	6	5	4	3	2	1	0
Field	seq_set[2:0]			vcom_l[4:0]				
Reset	0x2			0x00				
Access Type	Write, Read			Write, Read				

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BITFIELD	BITS	DESCRIPTION	DECODE
seq_set	7:5	Sequence selection bits.	0x0: Sequence 1. 0x1: Sequence 2. 0x2: Sequence 3. 0x3: Sequence 4. 0x4: Sequence 5. 0x5: Sequence 6. 0x6: Sequence 7. 0x7: Sequence 8.
vcom_l	4:0	Delta VCOM at at the temperature corresponding to VTEMP_L. This value sets the difference between the VCOM value at 25°C and that at VTEMP_L.	

VCOM_H1 (0x0B)

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	vcom_h1[4:0]				
Reset	–	–	–	0x00				
Access Type	–	–	–	Write, Read				

BITFIELD	BITS	DESCRIPTION
vcom_h1	4:0	Delta VCOM at VTEMP_H1. This value sets the difference between the VCOM value at 25°C and that at VTEMP_H1.

VCOM_H2 (0x0C)

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	vcom_h2[4:0]				
Reset	–	–	–	0x0				
Access Type	–	–	–	Write, Read				

BITFIELD	BITS	DESCRIPTION
vcom_h2	4:0	Delta VCOM at VTEMP_H2. This value sets the difference between the VCOM value at VTEMP_H1 and that at VTEMP_H2.

VTEMP25 (0x0D)

BIT	7	6	5	4	3	2	1	0
Field	vtemp25[7:0]							
Reset	0x0							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vtemp25	7:0	Voltage at TEMP pin at 25°C.

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VTEMP_L (0x0E)

BIT	7	6	5	4	3	2	1	0
Field	vtemp_l[7:0]							
Reset	0x0							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vtemp_l	7:0	Voltage at TEMP pin corresponding to low-temperature breakpoint in VCOM compensation curve.

VTEMP_H1 (0x0F)

BIT	7	6	5	4	3	2	1	0
Field	vtemp_h1[7:0]							
Reset	0x0							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vtemp_h1	7:0	Voltage at TEMP pin corresponding to first high-temperature breakpoint in VCOM compensation curve.

VTEMP_H2 (0x10)

BIT	7	6	5	4	3	2	1	0
Field	vtemp_h2[7:0]							
Reset	0x0							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vtemp_h2	7:0	Voltage at TEMP pin corresponding to second high-temperature breakpoint in VCOM compensation curve.

VCOM_MIN (0x11)

BIT	7	6	5	4	3	2	1	0
Field	vcom_min[7:0]							
Reset	0x0							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vcom_min	7:0	Lower limit for VCOM setting.

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VCOM_MAX (0x12)

BIT	7	6	5	4	3	2	1	0
Field	vcom_max[7:0]							
Reset	0xFF							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
vcom_max	7:0	Upper limit for VCOM setting.

AVDD_SET (0x13)

BIT	7	6	5	4	3	2	1	0
Field	–	–	avdd[5:0]					
Reset	–	–	0x1A					
Access Type	–	–	Write, Read					

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BITFIELD	BITS	DESCRIPTION	DECODE
avdd	5:0	Sets AVDD and NAVDD voltages.	0x0: 4.2 0x1: 4.3 0x2: 4.4 0x3: 4.5 0x4: 4.6 0x5: 4.7 0x6: 4.8 0x7: 4.9 0x8: 5 0x9: 5.1 0xA: 5.2 0xB: 5.3 0xC: 5.4 0xD: 5.5 0xE: 5.6 0xF: 5.7 0x10: 5.8 0x11: 5.9 0x12: 6 0x13: 6.1 0x14: 6.2 0x15: 6.3 0x16: 6.4 0x17: 6.5 0x18: 6.6 0x19: 6.7 0x1A: 6.8 0x1B: 6.9 0x1C: 7V 0x1D: 7.1 0x1E: 7.2 0x1F: 7.3 0x20: 7.4 0x21: 7.5 0x22: 7.6 0x23: 7.7 0x24: 7.8 0x25: 7.9 0x26: 8 0x27: 8.1 0x28: 8.2 0x29: 8.3 0x2A: 8.4 0x2B: 8.5 0x2C: 8.6 0x2D: 8.7 0x2E: 8.8 0x2F: 8.9 0x30: 9 0x31: 9.1 0x32: 9.2 0x33: 9.3 0x34: 9.4 0x35: 9.5 0x36: 9.6 0x37: 9.7 0x38: 9.8 0x39: 9.9 0x3A: 10

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BITFIELD	BITS	DESCRIPTION	DECODE
			0x3B: 10.1 0x3C: 10.2 0x3D: 10.3 0x3E: 10.4 0x3F: 10.5

VGON (0x14)

BIT	7	6	5	4	3	2	1	0
Field	–	cp_2stage	vgon[5:0]					
Reset	–	0x0	0x16					
Access Type	–	Write, Read	Write, Read					

BITFIELD	BITS	DESCRIPTION	DECODE
cp_2stage	6	Set this bit to 1 when using a two-stage charge-pump.	

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BITFIELD	BITS	DESCRIPTION	DECODE
vgon	5:0	Sets VG_{ON} voltage.	0x0: 7.6 0x1: 7.8 0x2: 8 0x3: 8.2 0x4: 8.4 0x5: 8.6 0x6: 8.8 0x7: 9 0x8: 9.2 0x9: 9.4 0xA: 9.6 0xB: 9.8 0xC: 10 0xD: 10.2 0xE: 10.4 0xF: 10.6 0x10: 10.8 0x11: 11 0x12: 11.2 0x13: 11.4 0x14: 11.6 0x15: 11.8 0x16: 12 0x17: 12.2 0x18: 12.4 0x19: 12.6 0x1A: 12.8 0x1B: 13 0x1C: 13.2 0x1D: 13.4 0x1E: 13.6 0x1F: 13.8 0x20: 14 0x21: 14.2 0x22: 14.4 0x23: 14.6 0x24: 14.8 0x25: 15 0x26: 15.2 0x27: 15.4 0x28: 15.6 0x29: 15.8 0x2A: 16 0x2B: 16.2 0x2C: 16.4 0x2D: 16.6 0x2E: 16.8 0x2F: 17 0x30: 17.2 0x31: 17.4 0x32: 17.6 0x33: 17.8 0x34: 18 0x35: 18.2 0x36: 18.4 0x37: 18.6 0x38: 18.8 0x39: 19 0x3A: 19.2

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BITFIELD	BITS	DESCRIPTION	DECODE
			0x3B: 19.4 0x3C: 19.6 0x3D: 19.8 0x3E: 20 0x3F: 20.2

VGOFF (0x15)

BIT	7	6	5	4	3	2	1	0
Field	–	–	vgoff[5:0]					
Reset	–	–	0x16					
Access Type	–	–	Write, Read					

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BITFIELD	BITS	DESCRIPTION	DECODE
vgoff	5:0	Sets VG_{OFF} voltage.	0x0: -5.6 0x1: -5.8 0x2: -6 0x3: -6.2 0x4: -6.4 0x5: -6.6 0x6: -6.8 0x7: -7 0x8: -7.2 0x9: -7.4 0xA: -7.6 0xB: -7.8 0xC: -8 0xD: -8.2 0xE: -8.4 0xF: -8.6 0x10: -8.8 0x11: -9 0x12: -9.2 0x13: -9.4 0x14: -9.6 0x15: -9.8 0x16: -10 0x17: -10.2 0x18: -10.4 0x19: -10.6 0x1A: -10.8 0x1B: -11 0x1C: -11.2 0x1D: -11.4 0x1E: -11.6 0x1F: -11.8 0x20: -12 0x21: -12.2 0x22: -12.4 0x23: -12.6 0x24: -12.8 0x25: -13 0x26: -13.2 0x27: -13.4 0x28: -13.6 0x29: -13.8 0x2A: -14 0x2B: -14.2 0x2C: -14.4 0x2D: -14.6 0x2E: -14.8 0x2F: -15 0x30: -15.2 0x31: -15.4 0x32: -15.6 0x33: -15.8 0x34: -16 0x35: -16.2 0x36: -16.4 0x37: -16.6 0x38: -16.8 0x39: -17 0x3A: -17.2

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BITFIELD	BITS	DESCRIPTION	DECODE
			0x3B: -17.4 0x3C: -17.6 0x3D: -17.8 0x3E: -18 0x3F: -18.2

NV_CONFIG (0x17)

Nonvolatile configuration register

BIT	7	6	5	4	3	2	1	0
Field	nv_int_sensor	nv_refresh	nv_en_ss	nv_fSW	nv_retry[1:0]		nv_tfault[1:0]	
Reset								
Access Type	Read Only	Read Only	Read Only	Read Only	Read Only		Read Only	

BITFIELD	BITS	DESCRIPTION	DECODE
nv_int_sensor	7	When this bit is 1 the internal temperature sensor is used.	
nv_refresh	6	When this bit is 1 the contents of the NV registers are automatically copied to the volatile registers every second.	
nv_en_ss	5	When this bit is 1 spread-spectrum is enabled.	
nv_fSW	4	Sets switching frequency.	0x0: 2.2MHz 0x1: 440kHz
nv_retry	3:2	Sets retry time after a fault.	
nv_tfault	1:0	Sets retry time after a fault.	

NV_DELAY-VCOM_LSB (0x18)

BIT	7	6	5	4	3	2	1	0
Field	nv_delayt1[1:0]		nv_delayt2[1:0]		nv_delayt3[1:0]		nv_T_comp_en	nv_vcom25_0
Reset							0x0	
Access Type	Read Only		Read Only		Read Only		Read Only	Read Only

BITFIELD	BITS	DESCRIPTION
nv_delayt1	7:6	Set delay t1 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.
nv_delayt2	5:4	Set delay t2 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.
nv_delayt3	3:2	Set delay t3 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.
nv_T_comp_en	1	When 1 this bit enables temperature compensation of output of the VCOM amplifier.
nv_vcom25_0	0	When 1 this bit enables temperature compensation of output of the VCOM amplifier.

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NV_VCOM25 (0x19)

BIT	7	6	5	4	3	2	1	0
Field	nv_vcom25[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vcom25	7:0	VCOM setting at 25°C.

NV_VCOM_L (0x1A)

BIT	7	6	5	4	3	2	1	0
Field	nv_seq_set[2:0]			nv_vcom_l[4:0]				
Reset								
Access Type	Read Only			Read Only				

BITFIELD	BITS	DESCRIPTION
nv_seq_set	7:5	Sequence selection bits.
nv_vcom_l	4:0	Delta VCOM at at the temperature corresponding to VTEMP_L. This value sets the difference between the VCOM value at 25°C and that at VTEMP_L.

NV_VCOM_H1 (0x1B)

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	nv_vcom_h1[4:0]				
Reset	–	–	–					
Access Type	–	–	–	Read Only				

BITFIELD	BITS	DESCRIPTION
nv_vcom_h1	4:0	Delta VCOM at VTEMP_H1. This value sets the difference between the VCOM value at 25°C and that at VTEMP_H1.

NV_VCOM_H2 (0x1C)

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	nv_vcom_h2[4:0]				
Reset	–	–	–					
Access Type	–	–	–	Read Only				

BITFIELD	BITS	DESCRIPTION
nv_vcom_h2	4:0	Delta VCOM at VTEMP_H2. This value sets the difference between the VCOM value at VTEMP_H1 and that at VTEMP_H2.

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NV_VTEMP25 (0x1D)

BIT	7	6	5	4	3	2	1	0
Field	nv_vtemp25[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vtemp25	7:0	Voltage at TEMP pin at 25°C.

NV_VTEMP_L (0x1E)

BIT	7	6	5	4	3	2	1	0
Field	nv_vtemp_l[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vtemp_l	7:0	Voltage at TEMP pin corresponding to low-temperature breakpoint in VCOM compensation curve.

NV_TEMP_H1 (0x1F)

BIT	7	6	5	4	3	2	1	0
Field	nv_vtemp_h1[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vtemp_h1	7:0	Voltage at TEMP pin corresponding to first high-temperature breakpoint in VCOM compensation curve.

NV_TEMP_H2 (0x20)

BIT	7	6	5	4	3	2	1	0
Field	nv_vtemp_h2[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vtemp_h2	7:0	Voltage at TEMP pin corresponding to second high-temperature breakpoint in VCOM compensation curve.

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NV_VCOM_MIN (0x21)

BIT	7	6	5	4	3	2	1	0
Field	nv_vcom_min[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vcom_min	7:0	Lower limit for VCOM setting.

NV_VCOM_MAX (0x22)

BIT	7	6	5	4	3	2	1	0
Field	nv_vcom_max[7:0]							
Reset								
Access Type	Read Only							

BITFIELD	BITS	DESCRIPTION
nv_vcom_max	7:0	Upper limit for VCOM setting.

NV_AVDD_SET (0x23)

BIT	7	6	5	4	3	2	1	0
Field	–	–	nv_avdd[5:0]					
Reset	–	–						
Access Type	–	–	Read Only					

BITFIELD	BITS	DESCRIPTION
nv_avdd	5:0	Sets AVDD and NAVDD voltages. See table for register 0x13.

NV_VGON (0x24)

BIT	7	6	5	4	3	2	1	0
Field	–	nv_cp_2stage	nv_vgon[5:0]					
Reset	–							
Access Type	–	Read Only	Read Only					

BITFIELD	BITS	DESCRIPTION
nv_cp_2stage	6	When this bit is set to 1 a two-stage charge-pump is used.
nv_vgon	5:0	Sets VG_{ON} voltage. See table for register 0x14.

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NV_VGOFF (0x25)

BIT	7	6	5	4	3	2	1	0
Field	–	–	nv_vgoff[5:0]					
Reset	–	–						
Access Type	–	–	Read Only					

BITFIELD	BITS	DESCRIPTION
nv_vgoff	5:0	Sets VG_{OFF} voltage. See table for register 0x15.

burn_otp_reg (0x78)

BIT	7	6	5	4	3	2	1	0
Field	burn_otp[7:0]							
Reset	0x0							
Access Type	Write Only							

BITFIELD	BITS	DESCRIPTION
burn_otp	7:0	Command to copy the contents of registers 0x07-0x15 to the nonvolatile registers 0x17-0x25.

reboot_otp_reg (0x79)

BIT	7	6	5	4	3	2	1	0
Field	reboot_otp[7:0]							
Reset								
Access Type	Write Only							

BITFIELD	BITS	DESCRIPTION
reboot_otp	7:0	Command to copy the contents of the nonvolatile registers 0x17-0x15 to the working registers 0x17-0x25.

soft_restart (0x7A)

BIT	7	6	5	4	3	2	1	0
Field	soft_restart[7:0]							
Reset	0x00							
Access Type	Write Only							

BITFIELD	BITS	DESCRIPTION
soft_restart	7:0	Command used to restart the device from a latched fault mode. All faults are cleared when this command is executed.

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Applications Information

Boost Converter

Boost Converter Inductor Selection

Three key inductor parameters must be specified for operation with the device: Inductance value (L), inductor saturation current (I_{SAT}), and DC resistance (R_{DC}). Use a 2.2µH inductor when the boost converter operates at 2.1MHz and 10µH at 420kHz.

The inductor's saturation rating must exceed the maximum current limit of 2.3A.

Boost Output Filter Capacitor Selection

The primary criterion for selecting the output filter capacitor is low effective series resistance (ESR). The product of the peak inductor current and the output filter capacitor's ESR determine the amplitude of the high-frequency ripple seen on the output voltage. For stability, the boost output-filter capacitor should have a value of 10µF or greater when using 2.1MHz switching.

To avoid a large drop on HVINP when AVDD is enabled, the capacitance on the HVINP node should be at least three times larger than that on AVDD.

Boost Input Filter Capacitor

Sufficient input capacitance must be used to avoid input voltage drop when transients are encountered on the AVDD or NAVDD outputs and when the AVDD switch is closed. If the IN voltage drops below 2.57V, the device is likely to reset so input capacitance must prevent this. The total value of capacitance depends on the expected transients and the series resistance in the IN connection. A good starting point is a total input capacitance of 2 x 22µF ceramic capacitors in parallel with 2 x 10µF ceramic capacitors. Depending on the particular application circumstances more or less capacitance may be needed.

Input capacitance requirements are significantly relaxed when an input voltage of 5V is used.

Setting the AVDD Voltage

The AVDD output voltage is set by writing a 6-bit value to the AVDD_SET register.

The NAVDD converter outputs a negative voltage whose absolute value is the same as AVDD.

NAVDD Inverting Regulator

NAVDD Regulator Inductor Selection

Three key inductor parameters must be specified for operation with the device: inductance value (L), inductor saturation current (I_{SAT}), and DC resistance (R_{DC}). Use a 2.2µH inductor when the converter operates at 2.1MHz and 10µH at 420kHz.

The inductor's saturation current rating must exceed the maximum current limit of 2.25A.

NAVDD External Diode Selection

Select a diode with a peak current rating of at least the LXN current limit (I_{LIMNH}) for use with the NAVDD output. The diode breakdown-voltage rating should exceed the sum of the maximum INN voltage and the absolute value of the NAVDD voltage. A Schottky diode improves the overall efficiency of the converter but should be selected to have low leakage at the maximum operating temperature.

NAVDD Output Capacitor Selection

The primary criterion for selecting the output filter capacitor is low ESR and capacitance value, as the NAVDD capacitor provides the load current when the internal switch is on. The voltage ripple on the NAVDD output has two components:

1. Ripple to due ESR which is the product of the peak inductor current and the output filter capacitor's ESR
2. Ripple due to bulk capacitance that can be determined as follows.

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$$\Delta V_{BULK} = \frac{I_{NAVDD} \times \frac{D}{f_{SW}}}{C_{NAVDD}}$$

For stability, the NAVDD output capacitor should have a value of 10µF or greater when using 2.1MHz switching frequency.

Setting the VG_{ON} and VG_{OFF} Output Voltages

The internal positive charge pump can output a voltage approximately three times AVDD. If a voltage of twice the HVINP voltage is sufficient leave the FC1+ and FC1- pins unconnected and set the cp_2stage bit.

For VG_{OFF}, the number of charge-pump stages should be chosen to ensure sufficient output voltage while maintaining the VG_{OFF} voltage within its permitted operating range.

The VG_{ON} output voltage is set by writing a 6-bit value to the vgon[5:0] field in the VG_{ON} register.

The VG_{OFF} voltage is set by writing a 6-bit value to the vgoff[5:0] field in the VG_{OFF} register.

VG_{ON} Voltage Higher than Three Times AVDD

In exceptional cases, it may be necessary to produce a VG_{ON} voltage greater than three times AVDD. In such cases, an external charge-pump circuit can be used as shown in Figure 4. When using the device in this way, leave the FC1-, FC1+ and FC2+ pins unconnected and set the cp_2stage bit to 1.

4x Charge Pump

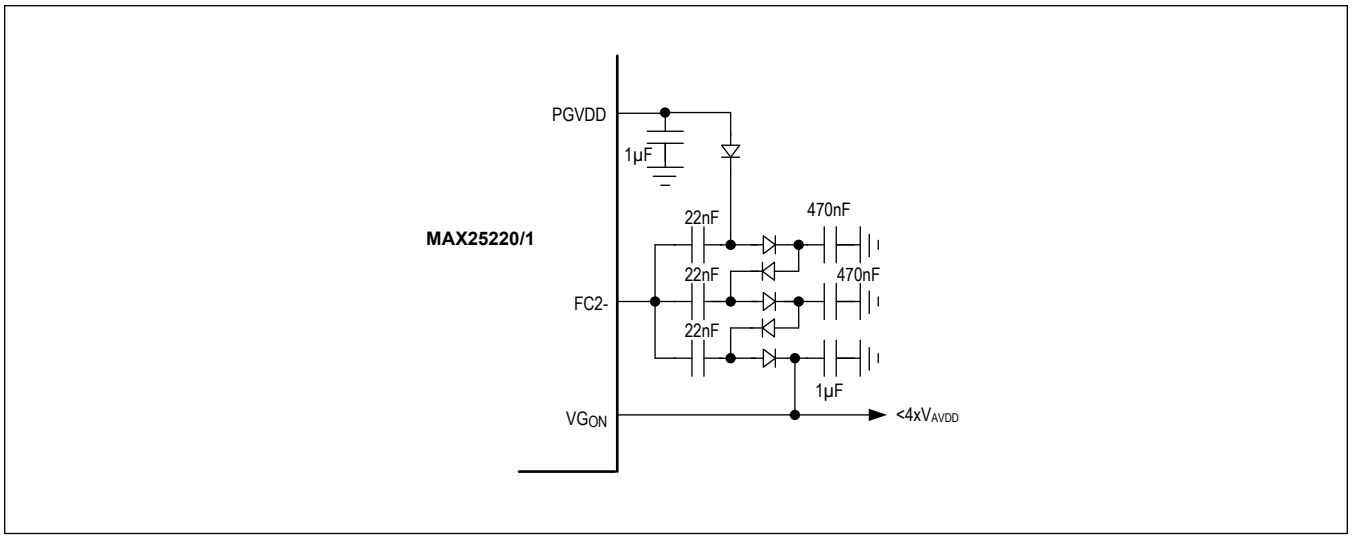


Figure 4. Quadrupler Charge-Pump at 2.1MHz

VCOM Block

VCB Transistor

Select an external npn transistor with a minimum current gain of 30. When designing the PCB, ensure that the parasitic capacitance between the base and collector of the npn is minimized to avoid oscillation. Note that high continuous DC current on VCOM causes very high power dissipation in the npn device and a device with low thermal resistance should therefore be selected.

VCOM Temperature Compensation Example

Assume that an NTC with 10kΩ resistance at +25°C is connected from TEMP to GND and that the R_{REF} resistor is of value 2400Ω. At various temperatures, the following voltages will be observed on R_{REF} and the ADC measurement result

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will be as follows:

Table 6. ADC Result vs Temperature

TEMPERATURE	NTC RESISTANCE	R_{REF} VOLTAGE	ADC RESULT	DESIRED VCOM VOLTAGE
-30°C	113kΩ	13mV	0x02	-1.09V
25°C	10kΩ	150mV	0x1F	-1V
60°C	3kΩ	500mV	0x66	-0.98V
85°C	1.5kΩ	1V	0xCD	-0.91V

The rightmost column of the previous table indicates the desired VCOM output voltage at each temperature, which will be the inflection points in the temperature compensation curve. The following values are written to the relevant registers (remembering that each LSB of the VCOM setting represents 6.83mV):

Table 7. VCOM Setting Example

REGISTER	FIELD	SETTING	NOTES
DELAYVCOM_LSB[7:0]	vcom25_0	0	9-bit value is 011011010 or 0xDA which corresponds to -1V
VCOM25	vcom25[7:0]	0x6D	
VCOM_L	vcom_l[4:0]	0x0D	Represents shift of -89mV from VCOM25
VCOM_H1	vcom_h1[4:0]	0x03	Represents shift of +20mV from VCOM25
VCOM_H2	vcom_h2[4:0]	0x0A	Represents shift of +68mV from VCOM_H1
VTEMP25	vtemp25[7:0]	0x1F	ADC result at +25°C
VTEMP_L	vtemp_l[7:0]	0x02	ADC result at -30°C
VTEMP_H1	vtemp_h1[7:0]	0x66	ADC result at +60°C
VTEMP_H2	vtemp_h2[7:0]	0xCD	ADC result at +85°C

With these settings, the VCOM output voltage at +25°C is -1V, while at the temperature represented by 13mV at the R_{REF} pin the VCOM voltage decreases to -1.09V as set by the VCOM_L register. Similarly, the VCOM_H1 and VCOM_H2 values are output on VCOM when the TEMP voltage is 500mV and 1V, respectively. In between these values the device interpolates the correct VCOM voltage value with a resolution of 6.83mV. The complete curve is shown in Figure 5.

When setting the values VTEMP_xx and VCOM_xx, it is important to avoid values which can cause wraparound in the temperature compensation algorithm thus possibly leading to sudden changes in the value of VCOM.

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Sample VCOM Temperature Compensation Curve

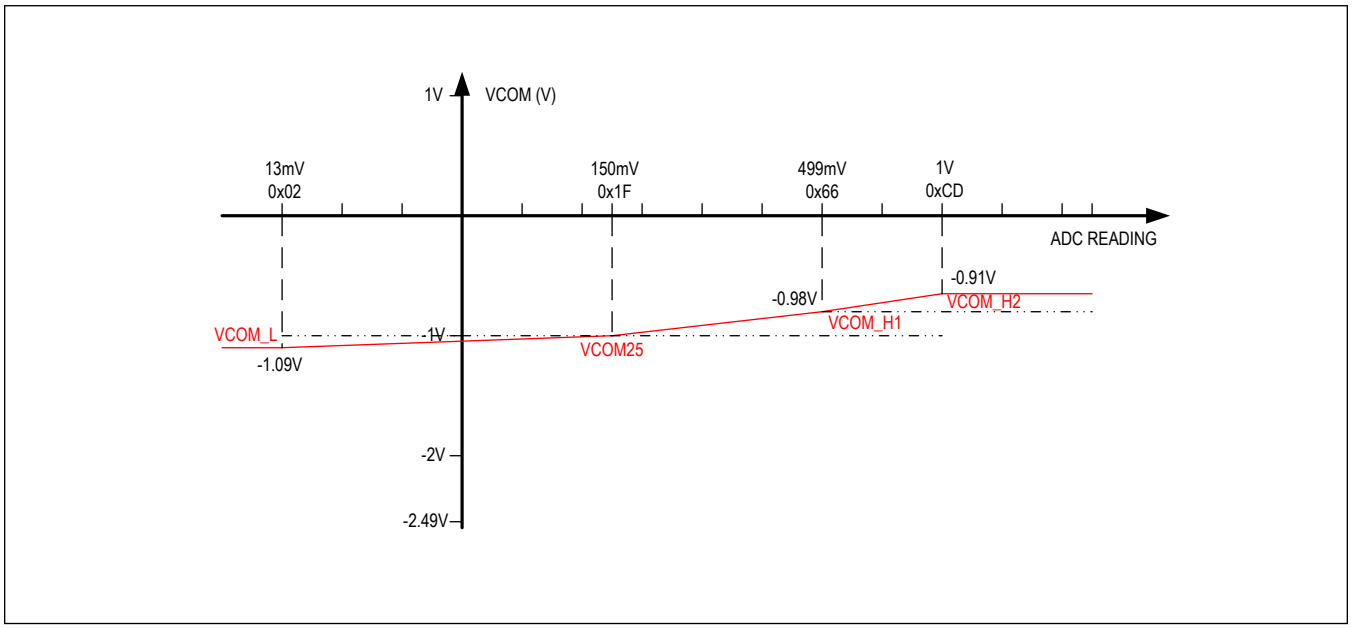


Figure 5. Sample VCOM Temperature Compensation Curve

Using the NV Memory

Follow the sequence below to perform nonvolatile programming of the device when the auto-refresh function is not used:

1. Apply a voltage between 3.3V and 5V to the IN and INN pins with the device in I^2C mode.
2. Write the desired values to be stored in OTP to the registers from 0x07 to 0x15.
3. Apply 8.5V to V_{PROG}.
4. Optionally wait to ensure the 8.5V at V_{PROG} is stable.
5. Send burn_otp_reg (write any value to 0x78) command. If parity is enabled ensure the overall parity is even by altering the final byte if necessary.
6. Wait 20ms.
7. If the nv_flt bit is 0, the write was successful, go to next step. If nv_flt = 1, perform re-try (steps 5, 6).
8. Send reboot_otp (write any value to 0x79) command.

Special care is required when performing nonvolatile programming with the auto-refresh feature enabled. In such cases follow the sequence below when at least one calibration has already been performed:

1. Apply a voltage between 3.3V and 5V to the IN and INN pins.
2. Write the desired values to be stored in NV memory to the registers from 0x07 to 0x15 (keep auto-refresh bit disabled until here).
3. Enable the auto-refresh feature.
4. Start polling one of the registers from 0x07 to 0x15 which has changed its value until that value gets refreshed to the older one (auto-refresh is active).
5. The following steps from #6 to #10 must be completed within 1s.
6. Write the desired values to be stored in OTP to the registers from 0x07 to 0x15 (including auto-refresh bit).
7. Apply 8.5V to V_{PROG}.
8. Optionally wait to ensure the 8.5V at V_{PROG} is stable.
9. Send burn_otp_reg (write any value to 0x78) command. If parity is enabled ensure the overall parity is even by

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altering the final byte if necessary.

10. Wait 20ms.
11. If the nv_flt bit is 0, the write was successful, go to next step. If nv_flt = 1, perform retry from step 2.
12. Send reboot_otp (write any value to 0x79) command.

The nonvolatile memory can be written to a total of six times.

Layout Considerations

The MAX25220/MAX25221/MAX25221B/MAX25221C include high-frequency switching converters to generate the voltages for TFT-LCDs. Take proper care while laying out the circuit board to ensure correct operation. The switching-converter portions of the circuit have nodes with very fast voltage changes that could lead to undesirable effects on the sensitive parts of the circuit as well as electromagnetic interference (EMI). Follow the guidelines below to reduce noise as much as possible:

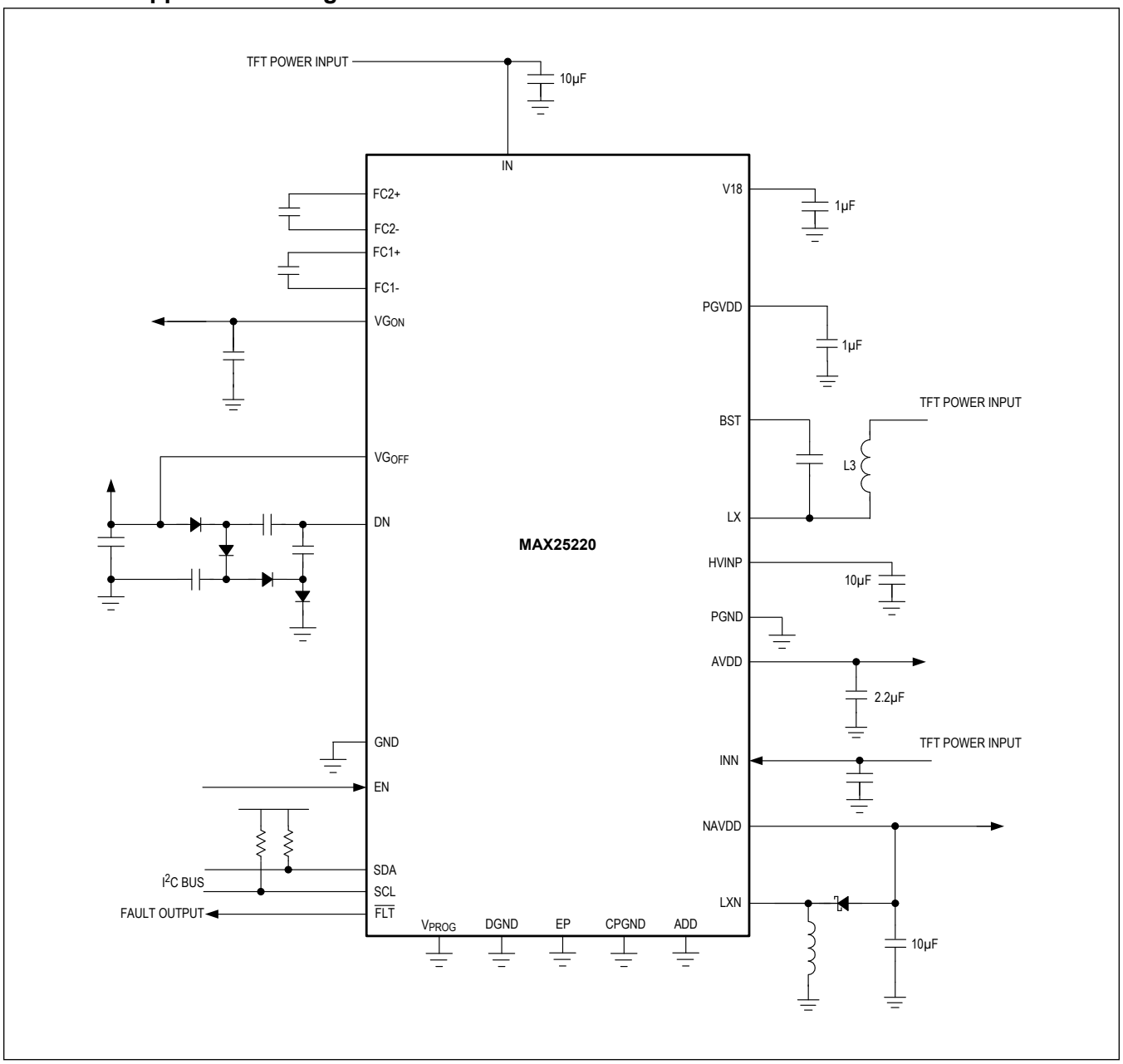
- Connect the bypass capacitors on IN and INN as close as possible to the device and connect the capacitor ground to the analog ground plane using vias close to the capacitor terminal. Ensure that the power connection to IN and INN uses a very wide trace or complete board layer to avoid input undervoltage problems.
- Connect the GND pin of the device to the analog ground plane using a via close to GND. Lay the analog ground plane on the inner layer, preferably next to the top layer. Use the analog ground plane to cover the entire area under critical signal components for the power converter.
- Have a power-ground plane for the switching-converter power circuit under the power components (i.e., input filter capacitor, output filter capacitor, inductor, MOSFET, rectifier diode, and current-sense resistor). Connect PGND to the power-ground plane closest to PGND. Connect all other ground connections to the power ground plane using vias close to the terminals.
- Minimize the copper area of all switching nodes to avoid EMI. Minimize the loop areas for the AVDD and NAVDD converters by placing all components close to the LXP and LXN pins. Place the input and output capacitor grounds close to each other. In the case of AVDD the input/output capacitor grounds should also connect directly to the PGND pin.
- Connect GND, CPGND, and PGND at the exposed pad of the device.
- Refer to the evaluation kit (EV kit) data sheet for a sample layout.

In addition, when using an external NTC temperature sensor for temperature compensation connect the grounded end directly to the grounded end of the R_{REF} resistor. This avoids possible differences in ground potential between different points on the circuit board.

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Typical Application Circuits

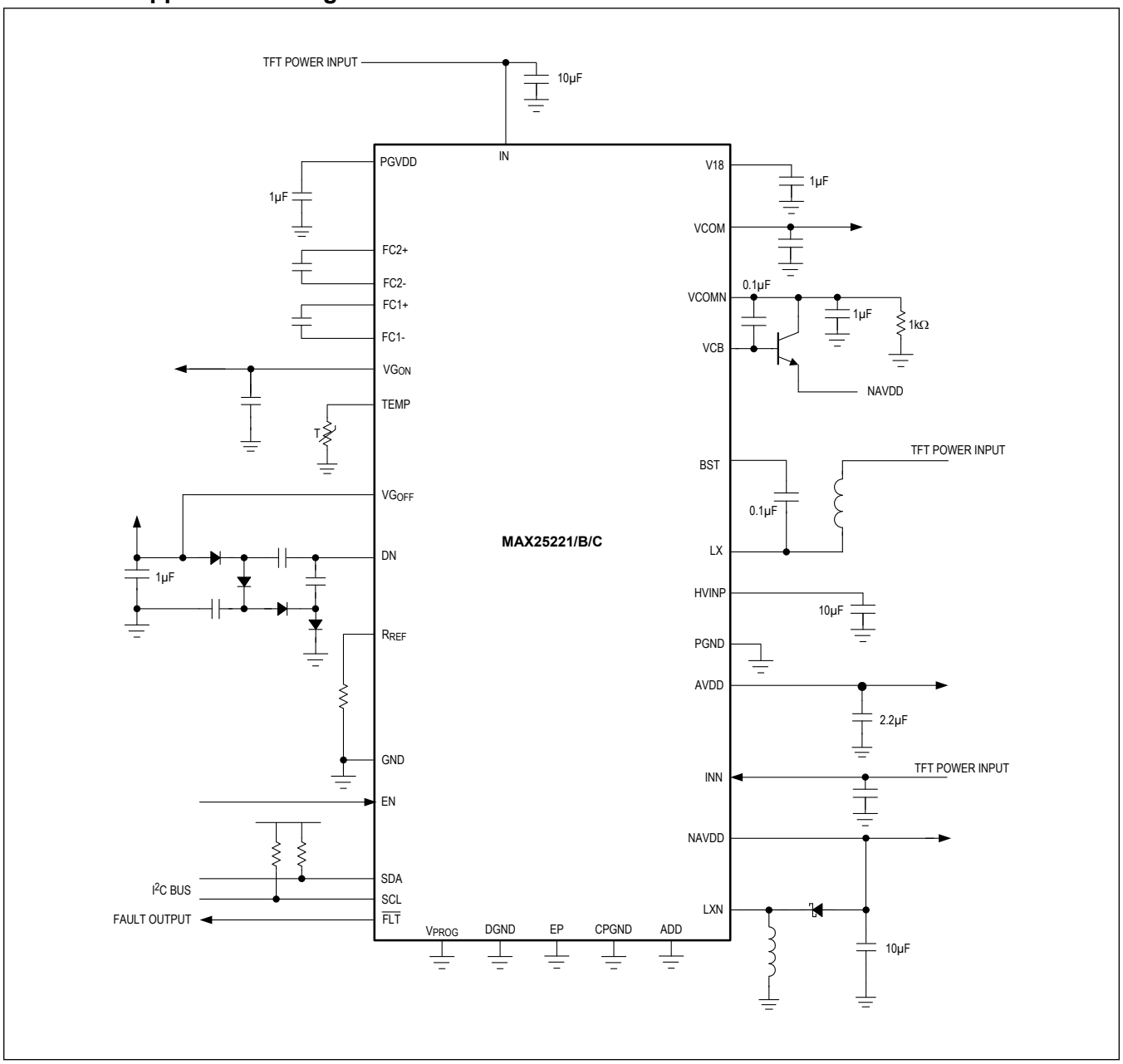
MAX25220 Applications Diagram



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Typical Application Circuits (continued)

MAX25221 Applications Diagram



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Ordering Information

PART NUMBER	TEMPERATURE RANGE	PIN-PACKAGE	FEATURES
MAX25220ATJ/V+	-40 to +125°C	32 TQFN-EP	Without VCOM buffer
MAX25221ATJ/V+	-40 to +125°C	32 TQFN-EP	With VCOM buffer
MAX25220ATJ/VY+	-40 to +125°C	32 SWTQFN-EP	Without VCOM buffer
MAX25221ATJ/VY+*	-40 to +125°C	32 SWTQFN-EP	With VCOM buffer
MAX25221BATJ/V+	-40 to +125°C	32 TQFN-EP	EN pin turn-on, VCOM buffer
MAX25221CATJ/V+	-40 to +125°C	32 TQFN-EP	EN pin turn-on, VCOM buffer, short-circuit check disabled on VG_{ON}/VG_{OFF}
MAX25221CATJ/VY+	-40 to +125°C	32 SWTQFN-EP	EN pin turn-on, VCOM buffer, short-circuit check disabled on VG_{ON}/VG_{OFF}

+ Denotes a lead(Pb)-free/RoHS-compliant package.

/V denotes an automotive-qualified part.

Y = Side-wettable package.

T Denotes tape-and-reel.

**Potential future product.*

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Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	5/20	Initial release	—
1	6/20	Removed future product notation from MAX25221ATJ/V+ *in Ordering Information*	54
2	6/20	Added *Typical Operating Characteristics*	14, 15
3	10/20	Updated *Package Information* and *Electrical Characteristics*; removed future product notation for MAX25220ATJ/VY+ in *Ordering Information*	7, 11, 54
4	11/20	Updated *Pin Descriptions* and *Ordering Information*	19, 54
5	8/21	Added information on nonvolatile memory writes; updated *Absolute Maximum Ratings*; added C version; updated inductor selection content	2, 6, 27, 29–31, 43, 51
6	6/25	Updated *Ordering Information*	55

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